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# ASSP for Power Management Applications

## 1 ch DC/DC Converter IC Built-in Switching FET & POWERGOOD function, PFM/PWM Synchronous Rectification, and Down Conversion Support

### MB39C006A

#### ■ DESCRIPTION

The MB39C006A is a current mode type 1-channel DC/DC converter IC built-in switching FET, synchronous rectification, and down conversion support. The device is integrated with a switching FET, oscillator, error amplifier, PFM/PWM control circuit, reference voltage source, and POWERGOOD circuit. External inductor and decoupling capacitor are needed only for the external component. MB39C006A is small, achieve a highly effective DC/DC converter in the full load range, this is suitable as the built-in power supply for handheld equipment such as mobile phone/PDA, DVDs, and HDDs.

#### ■ FEATURES

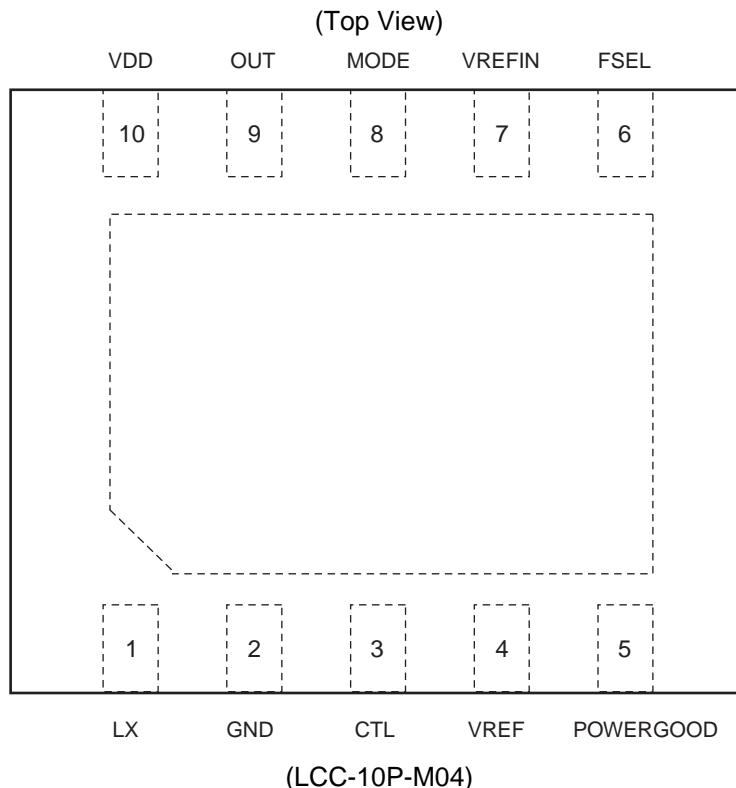
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|------------------------------------------------------------------------|-----------------------------------------------------------|
| • High efficiency                                                      | : 96% (Max)                                               |
| • Low current consumption                                              | : 30 $\mu$ A (at PFM)                                     |
| • Output current (DC/DC)                                               | : 800 mA (Max)                                            |
| • Input voltage range                                                  | : 2.5 V to 5.5 V                                          |
| • Operating frequency                                                  | : 2.0/3.2 MHz (Typ)                                       |
| • Built-in PWM operation fixed function                                |                                                           |
| • No flyback diode needed                                              |                                                           |
| • Low dropout operation                                                | : For 100% on duty                                        |
| • Built-in high-precision reference voltage generator                  | : 1.20 V $\pm$ 2%                                         |
| • Consumption current in shutdown mode                                 | : 1 $\mu$ A or less                                       |
| • Built-in switching FET                                               | : P-ch MOS 0.3 $\Omega$ (Typ) N-ch MOS 0.2 $\Omega$ (Typ) |
| • High speed for input and load transient response in the current mode |                                                           |
| • Over temperature protection                                          |                                                           |
| • Packaged in a compact package                                        | : SON10                                                   |

#### ■ APPLICATIONS

- Flash ROMs
- MP3 players
- Electronic dictionary devices
- Surveillance cameras
- Portable GPS navigators
- Mobile phones
- etc.

# MB39C006A

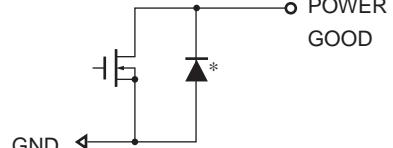
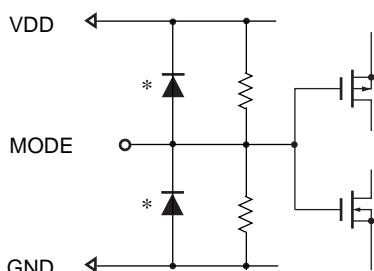
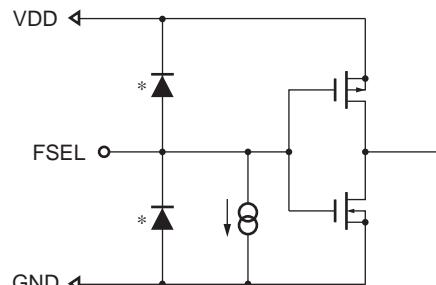
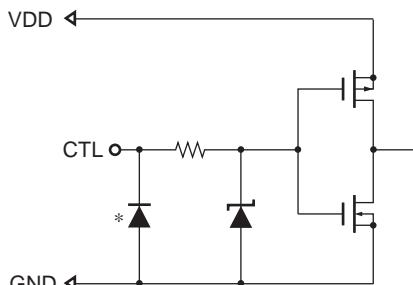
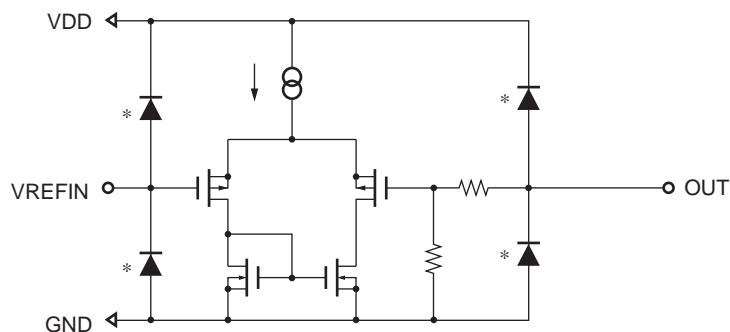
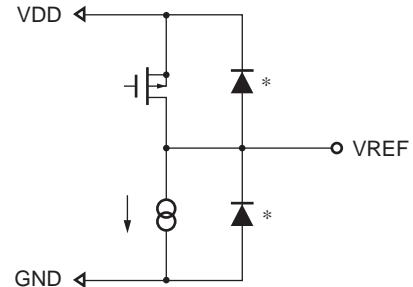
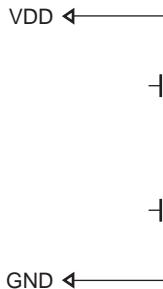
## ■ PIN ASSIGNMENT



## ■ PIN DESCRIPTIONS

| Pin No | Pin name  | I/O | Description                                                                           |
|--------|-----------|-----|---------------------------------------------------------------------------------------|
| 1      | LX        | O   | Inductor connection output pin. High impedance during shut down.                      |
| 2      | GND       | —   | Ground pin.                                                                           |
| 3      | CTL       | I   | Control input pin. (L : Shut down / H : Normal operation)                             |
| 4      | VREF      | O   | Reference voltage output pin.                                                         |
| 5      | POWERGOOD | O   | POWERGOOD circuit output pin. Internally connected to an N-ch MOS open drain circuit. |
| 6      | FSEL      | I   | Frequency switch pin.<br>(L (open) : 2.0 MHz, H : 3.2 MHz)                            |
| 7      | VREFIN    | I   | Error amplifier (Error Amp) non-inverted input pin.                                   |
| 8      | MODE      | I   | Operation mode switch pin.<br>(L : PFM/PWM mode, OPEN : PWM mode)                     |
| 9      | OUT       | I   | Output voltage feedback pin.                                                          |
| 10     | VDD       | —   | Power supply pin.                                                                     |

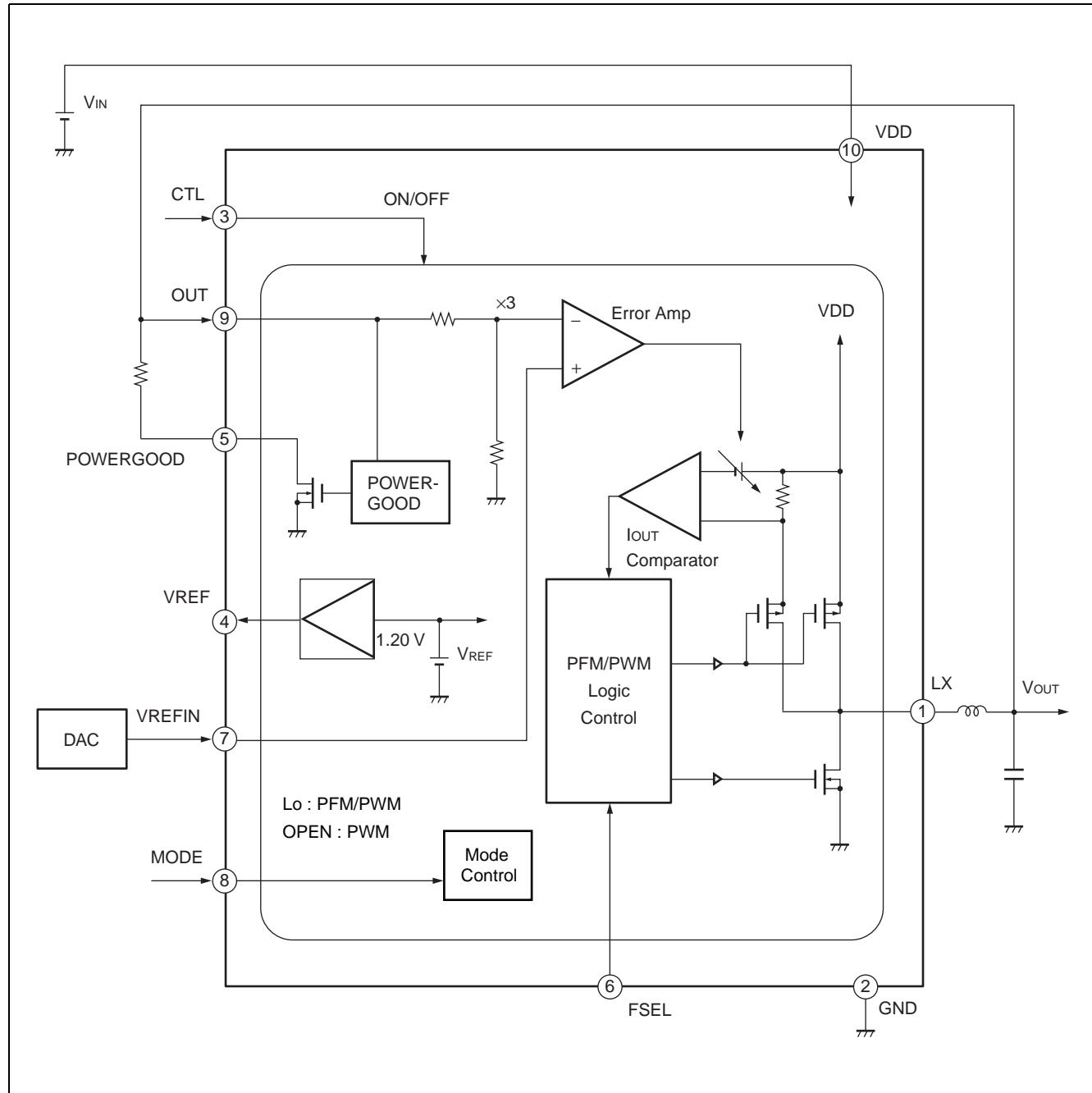
## ■ I/O PIN EQUIVALENT CIRCUIT DIAGRAM



\* : ESD Protection device

**MB39C006A**

## ■ BLOCK DIAGRAM



- **Current mode**

- Original voltage mode type:

Stabilize the output voltage by comparing two items below and on-duty control.

- Voltage ( $V_c$ ) obtained through negative feedback of the output voltage by Error Amp
- Reference triangular wave ( $V_{TRI}$ )

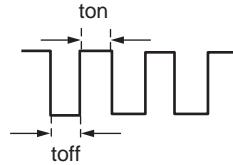
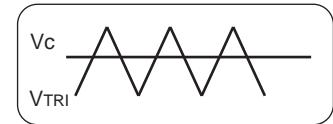
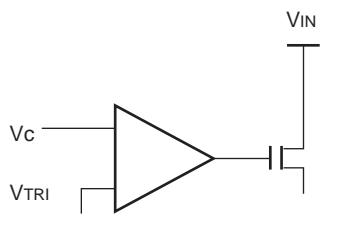
- Current mode type:

Instead of the triangular wave ( $V_{TRI}$ ), the voltage ( $V_{DET}$ ) obtained through I-V conversion of the sum of currents that flow in the oscillator (rectangular wave generation circuit) and SW FET is used.

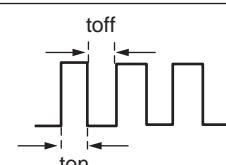
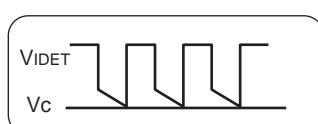
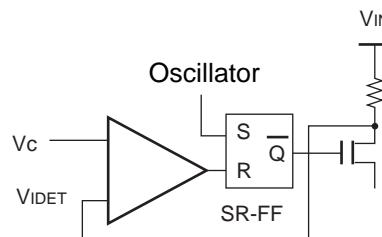
Stabilize the output voltage by comparing two items below and on-duty control.

- Voltage ( $V_c$ ) obtained through negative feedback of the output voltage by Error Amp
- Voltage ( $V_{DET}$ ) obtained through I-V conversion of the sum of current that flow in the oscillator (rectangular wave generation circuit) and SW FET

**Voltage mode type model**



**Current mode type model**



Note : The above models illustrate the general operation and an actual operation will be preferred in the IC.

## ■ FUNCTION OF EACH BLOCK

### • PFM/PWM Logic control circuit

In normal operation, frequency (2.0 MHz/3.2 MHz) which is set by the built-in oscillator (square wave oscillation circuit) controls the built-in P-ch MOS FET and N-ch MOS FET for the synchronous rectification operation. In the light load mode, the intermittent (PFM) operation is executed.

This circuit protects against pass-through current caused by synchronous rectification and against reverse current caused in a non-successive operation mode.

### • $I_{OUT}$ comparator circuit

This circuit detects the current ( $I_{LX}$ ) which flows to the external inductor from the built-in P-ch MOS FET.

By comparing  $V_{IDET}$  obtained through I-V conversion of peak current  $I_{PK}$  of  $I_{LX}$  with the Error Amp output, the built-in P-ch MOS FET is turned off via the PFM/PWM Logic Control circuit.

### • Error Amp phase compensation circuit

This circuit compares the output voltage to reference voltages such as VREF. The MB39C006A has a built-in phase compensation circuit that is designed to optimize the operation of the MB39C006A. This needs neither to be considered nor addition of a phase compensation circuit and an external phase compensation device.

### • VREF circuit

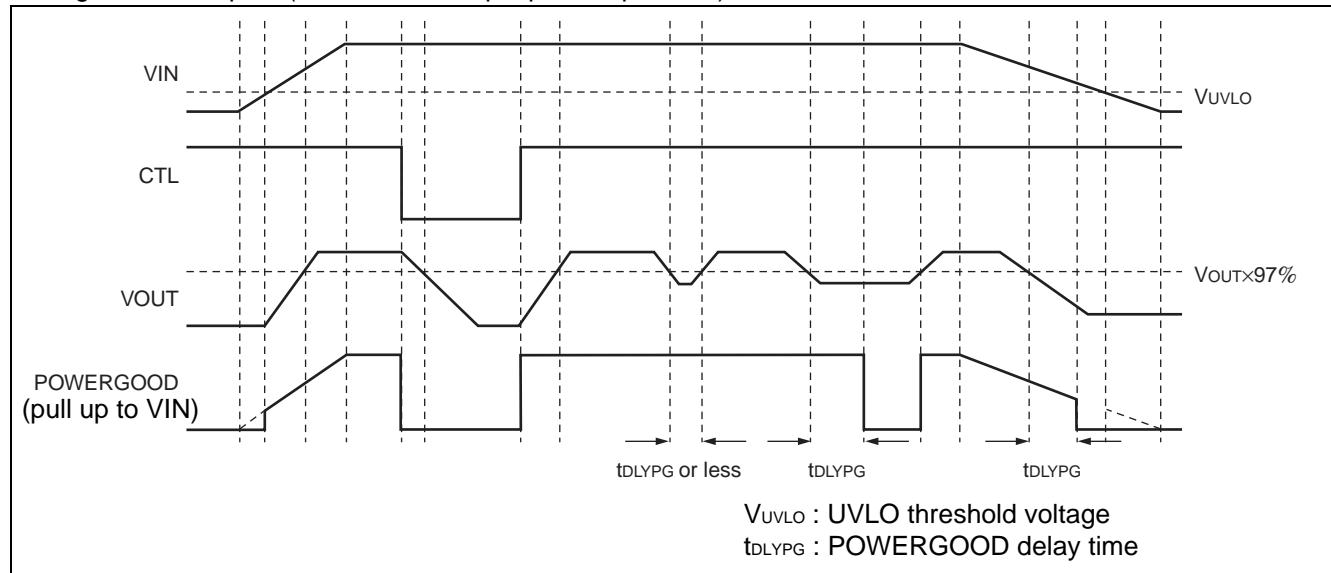
A high accuracy reference voltage is generated with BGR (bandgap reference) circuit. The output voltage is 1.20 V (Typ).

### • POWERGOOD circuit

The POWERGOOD circuit monitors the voltage at the OUT pin. The POWERGOOD pin is open drain output. Use the pin with pull-up using the external resistor in the normal operation.

When the CTL is at the H level, the POWERGOOD pin becomes the H level. However, if the output voltage drops because of over current and etc, the POWERGOOD pin becomes the L level.

Timing chart example : (POWERGOOD pin pulled up to VIN)



- **Protection circuit**

The MB39C006A has a built-in over-temperature protection circuit.

The over-temperature protection circuit turns off both N-ch and P-ch switching FETs when the junction temperature reaches +135 °C. When the junction temperature drops to + 110 °C, the switching FET returns to the normal operation.

Since the PFM/PWM control circuit of the MB39C006A is in the control method in current mode, the current peak value is also monitored and controlled as required.

- **FUNCTION TABLE**

| MODE           | Switching frequency | Input |      |      | Output              |             |               |
|----------------|---------------------|-------|------|------|---------------------|-------------|---------------|
|                |                     | CTL   | MODE | FSEL | OUTPUT pin voltage  | VREF        | POWERGOOD     |
| Shutdown mode  | —                   | L     | *    | *    | Output stop         | Output stop | Function stop |
| PFM/PWM mode   | 2.0 MHz             | H     | L    | L    | VOUT voltage output | 1.2 V       | Operation     |
| PWM fixed mode | 2.0 MHz             | H     | OPEN | L    | VOUT voltage output | 1.2 V       | Operation     |
| PFM/PWM mode   | 3.2 MHz             | H     | L    | H    | VOUT voltage output | 1.2 V       | Operation     |
| PWM fixed mode | 3.2 MHz             | H     | OPEN | H    | VOUT voltage output | 1.2 V       | Operation     |

\* : Don't care

## ■ ABSOLUTE MAXIMUM RATINGS

| Parameter                     | Symbol            | Condition                                | Rating |                            | Unit |
|-------------------------------|-------------------|------------------------------------------|--------|----------------------------|------|
|                               |                   |                                          | Min    | Max                        |      |
| Power supply voltage          | V <sub>DD</sub>   | VDD pin                                  | – 0.3  | + 6.0                      | V    |
| Signal input voltage          | V <sub>ISIG</sub> | OUT pin                                  | – 0.3  | V <sub>DD</sub> + 0.3      | V    |
|                               |                   | CTL, MODE, FSEL pins                     | – 0.3  | V <sub>DD</sub> + 0.3      |      |
|                               |                   | VREFIN pin                               | – 0.3  | V <sub>DD</sub> + 0.3      |      |
| POWERGOOD pull-up voltage     | V <sub>IPG</sub>  | POWERGOOD pin                            | – 0.3  | + 6.0                      | V    |
| LX voltage                    | V <sub>LX</sub>   | LX pin                                   | – 0.3  | V <sub>DD</sub> + 0.3      | V    |
| LX peak current               | I <sub>PK</sub>   | The upper limit value of I <sub>LX</sub> | —      | 1.8                        | A    |
| Power dissipation             | P <sub>D</sub>    | Ta ≤ + 25 °C                             | —      | 2632 <sup>*1, *2, *3</sup> | mW   |
|                               |                   |                                          | —      | 980 <sup>*1, *2, *4</sup>  |      |
|                               |                   | Ta = + 85 °C                             | —      | 1053 <sup>*1, *2, *3</sup> | mW   |
|                               |                   |                                          | —      | 392 <sup>*1, *2, *4</sup>  |      |
| Operating ambient temperature | T <sub>a</sub>    | —                                        | – 40   | + 85                       | °C   |
| Storage temperature           | T <sub>STG</sub>  | —                                        | – 55   | + 125                      | °C   |

\*1 : See "■ EXAMPLE OF STANDARD OPERATION CHARACTERISTICS • Power dissipation vs. Operating ambient temperature" for the package power dissipation of Ta from + 25 °C to + 85 °C.

\*2 : When mounted on a four-layer epoxy board of 11.7 cm × 8.4 cm

\*3 : IC is mounted on a four-layer epoxy board, which has thermal via, and the IC's thermal pad is connected to the epoxy board (Thermal via is 4 holes).

\*4 : IC is mounted on a four-layer epoxy board, which has no thermal via, and the IC's thermal pad is connected to the epoxy board.

Notes

- The use of negative voltages below – 0.3 V to the GND pin may create parasitic transistors on LSI lines, which can cause abnormal operation.
- This device can be damaged if the LX pin is short-circuited to VDD pin or GND pin.
- Take measures not to keep the FSEL pin falling below the GND pin potential of the MB39C006A as much as possible.

In addition to erroneous operation, the IC may latch up and destroy itself if 110 mA or more current flows from this pin.

**WARNING:** Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

## ■ RECOMMENDED OPERATING CONDITIONS

| Parameter            | Symbol      | Condition                                      | Value |     |      | Unit          |
|----------------------|-------------|------------------------------------------------|-------|-----|------|---------------|
|                      |             |                                                | Min   | Typ | Max  |               |
| Power supply voltage | $V_{DD}$    | —                                              | 2.5   | 3.7 | 5.5  | V             |
| VREFIN voltage       | $V_{REFIN}$ | —                                              | 0.15  | —   | 1.20 | V             |
| CTL voltage          | $V_{CTL}$   | —                                              | 0     | —   | 5.0  | V             |
| LX current           | $I_{LX}$    | —                                              | —     | —   | 800  | mA            |
| POWERGOOD current    | $I_{PG}$    | —                                              | —     | —   | 1    | mA            |
| VREF output current  | $I_{ROUT}$  | $2.5 \text{ V} \leq V_{DD} \leq 3.0 \text{ V}$ | —     | —   | 0.5  | mA            |
|                      |             | $3.0 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$ | —     | —   | 1    |               |
| Inductor value       | L           | $f_{osc1} = 2.0 \text{ MHz (FSEL = L)}$        | —     | 2.2 | —    | $\mu\text{H}$ |
|                      |             | $f_{osc2} = 3.2 \text{ MHz (FSEL = H)}$        | —     | 1.5 | —    |               |

Note : The output current from this device has a situation to decrease if the power supply voltage ( $V_{IN}$ ) and the DC/DC converter output voltage ( $V_{OUT}$ ) differ only by a small amount. This is a result of slope compensation and will not damage this device.

**WARNING:** The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

## ■ ELECTRICAL CHARACTERISTICS

(Ta = + 25 °C, VDD = 3.7 V, VOUT setting value = 2.5 V, MODE = 0 V)

| Parameter                | Symbol                                       | Pin No. | Condition                       | Value                              |        |        | Unit   |    |
|--------------------------|----------------------------------------------|---------|---------------------------------|------------------------------------|--------|--------|--------|----|
|                          |                                              |         |                                 | Min                                | Typ    | Max    |        |    |
| DC/DC converter block    | Input current                                | 7       | VREFIN = 0.833 V                | -100                               | 0      | + 100  | nA     |    |
|                          |                                              |         | VREFIN = 0.15 V                 | -100                               | 0      | + 100  | nA     |    |
|                          |                                              |         | VREFIN = 1.20 V                 | -100                               | 0      | + 100  | nA     |    |
|                          | Output voltage                               | 9       | VREFIN = 0.833 V, OUT = -100 mA | 2.45                               | 2.50   | 2.55   | V      |    |
|                          | Input stability                              |         | 2.5 V ≤ VDD ≤ 5.5 V *1          | —                                  | 10     | —      | mV     |    |
|                          | Load stability                               |         | - 100 mA ≥ OUT ≥ - 800 mA       | —                                  | 10     | —      | mV     |    |
|                          | Out pin input impedance                      |         | OUT = 2.0 V                     | 0.6                                | 1.0    | 1.5    | MΩ     |    |
|                          | LX peak current                              | 1       | Output shorted to GND           | 0.9                                | 1.2    | 1.7    | A      |    |
|                          | PFM/PWM switch current                       |         | FSEL = 0 V, L = 2.2 μH          | —                                  | 30     | —      | mA     |    |
|                          | Oscillation frequency                        |         | FSEL = 0 V                      | 1.6                                | 2.0    | 2.4    | MHz    |    |
|                          |                                              |         | FSEL = 3.7 V                    | 2.56                               | 3.20   | 3.84   | MHz    |    |
| Protection circuit block | Rise delay time                              | tPG     | 3, 9                            | C1 = 4.7 μF, OUT = 0 A, VOUT = 90% | —      | 45     | 80     | μs |
|                          | SW NMOS FET OFF voltage                      | VNOFF   | 1                               | —                                  | —      | -20*   | —      | mV |
|                          | SW PMOS FET ON resistance                    | RONP    |                                 | LX = -100 mA                       | —      | 0.30   | 0.47   | Ω  |
|                          | SW NMOS FET ON resistance                    | RONN    |                                 | LX = -100 mA                       | —      | 0.20   | 0.36   | Ω  |
|                          | LX leak current                              | ILEAKM  |                                 | 0 ≤ LX ≤ VDD*2                     | -1.0   | —      | + 8.0  | μA |
|                          |                                              | ILEAKH  |                                 | VDD = 5.5 V, 0 ≤ LX ≤ VDD*2        | -2.0   | —      | + 16.0 | μA |
|                          | Over temperature protection (Junction Temp.) | TOTPH   | 10                              | —                                  | + 120* | + 135* | + 155* | °C |
|                          |                                              | TOTPL   |                                 |                                    | + 95*  | + 110* | + 130* | °C |
|                          | UVLO threshold voltage                       | VTHH    |                                 | —                                  | 2.07   | 2.20   | 2.33   | V  |
|                          |                                              | VTHL    |                                 | —                                  | 1.92   | 2.05   | 2.18   | V  |
|                          | UVLO hysteresis width                        | VHYS    |                                 | —                                  | 0.08   | 0.15   | 0.25   | V  |

\* : This value isn't be specified. This should be used as a reference to support designing the circuits.

(Continued)

(Continued)

(Ta = + 25 °C, VDD = 3.7 V, VOUT setting value = 2.5 V, MODE = 0 V)

| Parameter               |                                                          | Symbol              | Pin No. | Condition                                       | Value                               |                                     |                                     | Unit |
|-------------------------|----------------------------------------------------------|---------------------|---------|-------------------------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|------|
|                         |                                                          |                     |         |                                                 | Min                                 | Typ                                 | Max                                 |      |
| POWER-GOOD block        | POWERGOOD threshold voltage                              | V <sub>THPG</sub>   | 5       | *3                                              | V <sub>REFIN</sub><br>× 3<br>× 0.93 | V <sub>REFIN</sub><br>× 3<br>× 0.97 | V <sub>REFIN</sub><br>× 3<br>× 0.99 | V    |
|                         | POWERGOOD delay time                                     | t <sub>DLYPG1</sub> |         | FSEL = 0 V                                      | —                                   | 250                                 | —                                   | μs   |
|                         |                                                          | t <sub>DLYPG2</sub> |         | FSEL = 3.7 V                                    | —                                   | 170                                 | —                                   | μs   |
|                         | POWERGOOD output voltage                                 | V <sub>OL</sub>     |         | POWERGOOD = 250 μA                              | —                                   | —                                   | 0.1                                 | V    |
|                         | POWERGOOD output current                                 | I <sub>OH</sub>     |         | POWERGOOD = 5.5 V                               | —                                   | —                                   | 1.0                                 | μA   |
| Control block           | CTL threshold voltage                                    | V <sub>THHCT</sub>  | 3       | —                                               | 0.55                                | 0.95                                | 1.45                                | V    |
|                         |                                                          | V <sub>THLCT</sub>  |         | —                                               | 0.40                                | 0.80                                | 1.30                                | V    |
|                         | CTL pin input current                                    | I <sub>ICTL</sub>   |         | CTL = 3.7 V                                     | —                                   | —                                   | 1.0                                 | μA   |
|                         | MODE threshold voltage                                   | V <sub>THMMD</sub>  | 8       | OPEN setting                                    | —                                   | 1.5                                 | —                                   | V    |
|                         |                                                          | V <sub>THLMD</sub>  |         | —                                               | —                                   | —                                   | 0.4                                 | V    |
|                         | MODE pin input current                                   | I <sub>LM</sub>     |         | MODE = 0 V                                      | —0.8                                | —0.4                                | —                                   | μA   |
|                         | FSEL threshold voltage                                   | V <sub>THHFS</sub>  | 6       | —                                               | 2.96                                | —                                   | —                                   | V    |
|                         |                                                          | V <sub>THLFS</sub>  |         | —                                               | —                                   | —                                   | 0.74                                | V    |
| Reference voltage block | VREF voltage                                             | V <sub>REF</sub>    | 4       | VREF = -2.7 μA, OUT = -100 mA                   | 1.176                               | 1.200                               | 1.224                               | V    |
|                         | VREF load stability                                      | LOADREF             |         | VREF = -1.0 mA                                  | —                                   | —                                   | 20                                  | mV   |
| General                 | Shut down power supply current                           | I <sub>VDD1</sub>   | 10      | CTL = 0 V, All circuits in OFF state            | —                                   | —                                   | 1.0                                 | μA   |
|                         |                                                          | I <sub>VDD1H</sub>  |         | CTL = 0 V, VDD = 5.5 V                          | —                                   | —                                   | 1.0                                 | μA   |
|                         | Power supply current at DC/DC operation (PFM mode)       | I <sub>VDD2</sub>   |         | CTL = 3.7 V, MODE = 0 V, OUT = 0 A              | —                                   | 30                                  | 48                                  | μA   |
|                         | Power supply current at DC/DC operation (PWM fixed mode) | I <sub>VDD2</sub>   |         | CTL = 3.7 V, MODE = OPEN, OUT = 0 A, FSEL = 0 V | —                                   | 4.8                                 | 8.0                                 | mA   |
|                         | Power-on invalid current                                 | I <sub>VDD</sub>    |         | CTL = 3.7 V, VOUT = 90%*4                       | —                                   | 800                                 | 1500                                | μA   |

\*1 : The minimum value of V<sub>DD</sub> is the 2.5 V or V<sub>OUT</sub> setting value + 0.6 V, whichever is higher.

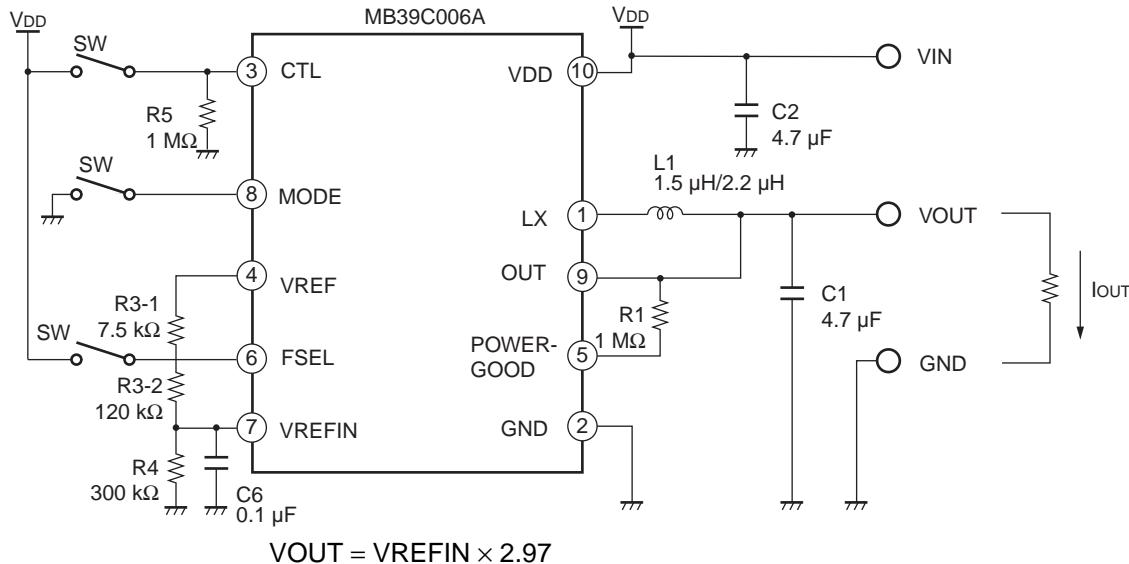
\*2 : The + leak at the LX pin includes the current of the internal circuit.

\*3 : Detected with respect to the output voltage setting value of V<sub>REFIN</sub>

\*4 : Current consumption based on 100% ON-duty (High side FET in full ON state). The SW FET gate drive current is not included because the device is in full ON state (no switching operation). Also the load current is not included.

# MB39C006A

## ■ TEST CIRCUIT FOR MEASURING TYPICAL OPERATING CHARACTERISTICS



| Component    | Specification    | Vendor     | Part Number                  | Remark                        |
|--------------|------------------|------------|------------------------------|-------------------------------|
| R1           | 1 MΩ             | KOA        | RK73G1JTTD D 1 MΩ            |                               |
| R3-1<br>R3-2 | 7.5 kΩ<br>120 kΩ | SSM<br>SSM | RR0816-752-D<br>RR0816-124-D | At VOUT = 2.5 V setting       |
| R4           | 300 kΩ           | SSM        | RR0816-304-D                 |                               |
| R5           | 1 MΩ             | KOA        | RK73G1JTTD D 1 MΩ            |                               |
| C1           | 4.7 μF           | TDK        | C2012JB1A475K                |                               |
| C2           | 4.7 μF           | TDK        | C2012JB1A475K                |                               |
| C6           | 0.1 μF           | TDK        | C1608JB1H104K                | For adjusting slow start time |
| L1           | 2.2 μH           | TDK        | VLF4012AT-2R2M               | 2.0 MHz operation             |
|              | 1.5 μH           | TDK        | VLF4012AT-1R5M               | 3.2 MHz operation             |

Note : These components are recommended based on the operating tests authorized.

TDK : TDK Corporation

SSM : SUSUMU Co., Ltd

KOA : KOA Corporation

## ■ APPLICATION NOTES

### [1] Selection of components

- Selection of an external inductor

Basically it dose not need to design inductor. The MB39C006A is designed to operate efficiently with a 2.2  $\mu$ H (2.0 MHz operation) or 1.5  $\mu$ H (3.2 MHz operation) external inductor.

The inductor should be rated for a saturation current higher than the LX peak current value during normal operating conditions, and should have a minimal DC resistance. (100 m $\Omega$  or less is recommended.)

The LX peak current value  $I_{PK}$  is obtained by the following formula.

$$I_{PK} = I_{OUT} + \frac{V_{IN} - V_{OUT}}{L} \times \frac{D}{fosc} \times \frac{1}{2} = I_{OUT} + \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{2 \times L \times fosc \times V_{IN}}$$

$L$  : External inductor value

$I_{OUT}$  : Load current

$V_{IN}$  : Power supply voltage

$V_{OUT}$  : Output setting voltage

$D$  : ON- duty to be switched( =  $V_{OUT}/V_{IN}$ )

$fosc$  : Switching frequency (2.0 MHz or 3.2 MHz)

ex) At  $V_{IN} = 3.7$  V,  $V_{OUT} = 2.5$  V,  $I_{OUT} = 0.8$  A,  $L = 2.2 \mu$ H,  $fosc = 2.0$  MHz

The maximum peak current value  $I_{PK}$ ;

$$I_{PK} = I_{OUT} + \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{2 \times L \times fosc \times V_{IN}} = 0.8 \text{ A} + \frac{(3.7 \text{ V} - 2.5 \text{ V}) \times 2.5 \text{ V}}{2 \times 2.2 \mu\text{H} \times 2.0 \text{ MHz} \times 3.7 \text{ V}} \approx 0.89 \text{ A}$$

- I/O capacitor selection

• Select a low equivalent series resistance (ESR) for the VDD input capacitor to suppress dissipation from ripple currents.

• Also select a low equivalent series resistance (ESR) for the output capacitor. The variation in the inductor current causes ripple currents on the output capacitor which, in turn, causes ripple voltages an output equal to the amount of variation multiplied by the ESR value. The output capacitor value has a significant impact on the operating stability of the device when used as a DC/DC converter. Therefore, FUJITSU MICROELECTRONICS generally recommends a 4.7  $\mu$ F capacitor, or a larger capacitor value can be used if ripple voltages are not suitable. If the  $V_{IN}/V_{OUT}$  voltage difference is within 0.6 V, the use of a 10  $\mu$ F output capacitor value is recommended.

- Types of capacitors

Ceramic capacitors are effective for reducing the ESR and afford smaller DC/DC converter circuit. However, power supply functions as a heat generator, therefore avoid to use capacitor with the F-temperature rating ( - 80% to + 20%). FUJITSU MICROELECTRONICS recommends capacitors with the B-temperature rating (  $\pm$  10% to  $\pm$  20% ).

Normal electrolytic capacitors are not recommended due to their high ESR.

Tantalum capacitor will reduce ESR, however, it is dangerous to use because it turns into short mode when damaged. If you insist on using a tantalum capacitor, FUJITSU MICROELECTRONICS recommends the type with an internal fuse.

# MB39C006A

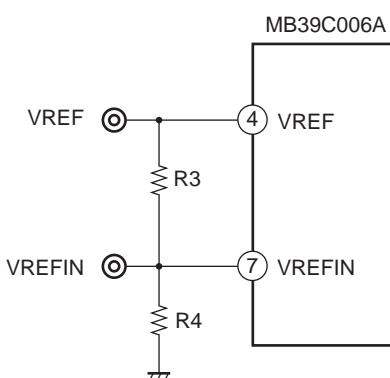
## [2] Output voltage setting

The output voltage  $V_{OUT}$  of the MB39C006A is defined by the voltage input to VREFIN. Supply the voltage for inputting to VREFIN from an external power supply, or set the VREF output by dividing it with resistors.

The output voltage when the VREFIN voltage is set by dividing the VREF voltage with resistors is shown in the following formula.

$$V_{OUT} = 2.97 \times V_{REFIN}, \quad V_{REFIN} = \frac{R4}{R3 + R4} \times V_{REF}$$

$(V_{REF} = 1.20 \text{ V})$



Note : See "■ APPLICATIN CIRCUIT EXAMPLES" for an example of this circuit.

Although the output voltage is defined according to the dividing ratio of resistance, select the resistance value so that the current flowing through the resistance does not exceed the VREF current rating (1 mA).

## [3] About conversion efficiency

The conversion efficiency can be improved by reducing the loss of the DC/DC converter circuit.

The total loss ( $P_{LOSS}$ ) of the DC/DC converter is roughly divided as follows :

$$P_{LOSS} = P_{CONT} + P_{SW} + P_C$$

$P_{CONT}$  : Control system circuit loss (The power to operate the MB39C006A, including the gate driving power for internal SW FETs)

$P_{SW}$  : Switching loss (The loss caused during the switch of the IC's internal SW FETs)

$P_C$  : Continuity loss (The loss caused when currents flow through the IC's internal SW FETs and external circuits )

The IC's control circuit loss ( $P_{CONT}$ ) is extremely small, several tens of mW\* with no load.

As the IC contains FETs which can switch faster with less power, the continuity loss ( $P_C$ ) is more predominant as the loss during heavy-load operation than the control circuit loss ( $P_{CONT}$ ) and switching loss ( $P_{SW}$ ).

\* : The loss in the successive operation mode. This IC suppresses the loss in order to execute the PFM operation in the low load mode (less than 100  $\mu$ A in no load mode). Mode is changed by the current peak value  $I_{PK}$  which flows into switching FET. The threshold value is about 30 mA.

Furthermore, the continuity loss ( $P_c$ ) is divided roughly into the loss by internal SW FET ON-resistance and by external inductor series resistance.

$$P_c = I_{OUT}^2 \times (R_{DC} + D \times R_{ONP} + (1 - D) \times R_{ONN})$$

D : Switching ON-duty cycle ( $= V_{OUT} / V_{IN}$ )

$R_{ONP}$  : Internal P-ch SW FET ON resistance

$R_{ONN}$  : Internal N-ch SW FET ON resistance

$R_{DC}$  : External inductor series resistance

$I_{OUT}$  : Load current

The above formula indicates that it is important to reduce RDC as much as possible to improve efficiency by selecting components.

#### [4] Power dissipation and heat considerations

The IC is so efficient that no consideration is required in most of the cases. However, if the IC is used at a low power supply voltage, heavy load, high output voltage, or high temperature, it requires further consideration for higher efficiency.

The internal loss (P) is roughly obtained from the following formula :

$$P = I_{OUT}^2 \times (D \times R_{ONP} + (1 - D) \times R_{ONN})$$

D : Switching ON-duty cycle ( $= V_{OUT} / V_{IN}$ )

$R_{ONP}$  : Internal P-ch SW FET ON resistance

$R_{ONN}$  : Internal N-ch SW FET ON resistance

$I_{OUT}$  : Output current

The loss expressed by the above formula is mainly continuity loss. The internal loss includes the switching loss and the control circuit loss as well but they are so small compared to the continuity loss they can be ignored.

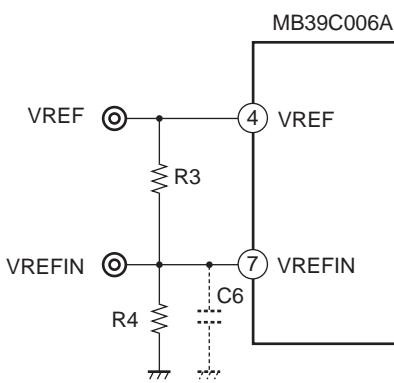
In the MB39C006A with  $R_{ONP}$  greater than  $R_{ONN}$ , the larger the on-duty cycle, the greater the loss.

When assuming  $V_{IN} = 3.7$  V,  $T_a = +70$  °C for example,  $R_{ONP} = 0.42$  Ω and  $R_{ONN} = 0.36$  Ω according to the graph "MOS FET ON resistance vs. Operating ambient temperature". The IC's internal loss P is 144 mW at  $V_{OUT} = 2.5$  V and  $I_{OUT} = 0.6$  A. According to the graph "Power dissipation vs. Operating ambient temperature", the power dissipation at an operating ambient temperature  $T_a$  of +70 °C is 539 mW and the internal loss is smaller than the power dissipation.

# MB39C006A

## [5] Transient response

Normally,  $I_{out}$  is suddenly changed while  $V_{IN}$  and  $V_{OUT}$  are maintained constant, responsiveness including the response time and overshoot/undershoot voltage is checked. As the MB39C006A has built-in Error Amp with an optimized design, it shows good transient response characteristics. However, if ringing upon sudden change of the load is high due to the operating conditions, add capacitor  $C_6$  (e.g. 0.1  $\mu$ F). (Since this capacitor  $C_6$  changes the start time, check the start waveform as well.) This action is not required for DAC input.



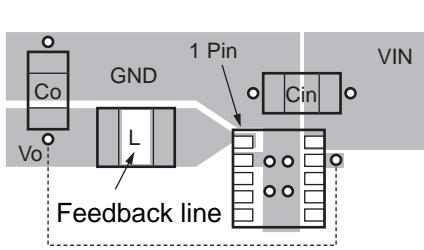
## [6] Board layout, design example

The board layout needs to be designed to ensure the stable operation of the MB39C006A.

Follow the procedure below for designing the layout.

- Arrange the input capacitor ( $C_{in}$ ) as close as possible to both the VDD and GND pins. Make a through hole (TH) near the pins of this capacitor if the board has planes for power and GND.
- Large AC currents flow between the MB39C006A and the input capacitor ( $C_{in}$ ), output capacitor ( $C_o$ ), and external inductor (L). Group these components as close as possible to the MB39C006A to reduce the overall loop area occupied by this group. Also try to mount these components on the same surface and arrange wiring without through hole wiring. Use thick, short, and straight routes to wire the net (The layout by planes is recommended.).
- The feedback wiring to the OUT should be wired from the voltage output pin closest to the output capacitor ( $C_o$ ). The OUT pin is extremely sensitive and should thus be kept wired away from the LX pin of the MB39C006A as far as possible.
- If applying voltage to the VREFIN pin through dividing resistors, arrange the resistors so that the wiring can be kept as short as possible. Also arrange them so that the GND pin of the VREFIN resistor is close to the IC's GND pin. Further, provide a GND exclusively for the control line so that the resistor can be connected via a path that does not carry current. If installing a bypass capacitor for the VREFIN, put it close to the VREFIN pin.
- Try to make a GND plane on the surface to which the MB39C006A will be mounted. For efficient heat dissipation when using the SON 10 package, FUJITSU MICROELECTRONICS recommends providing a thermal via in the footprint of the thermal pad.

### Layout Example of IC SW components



## • Notes for Circuit Design

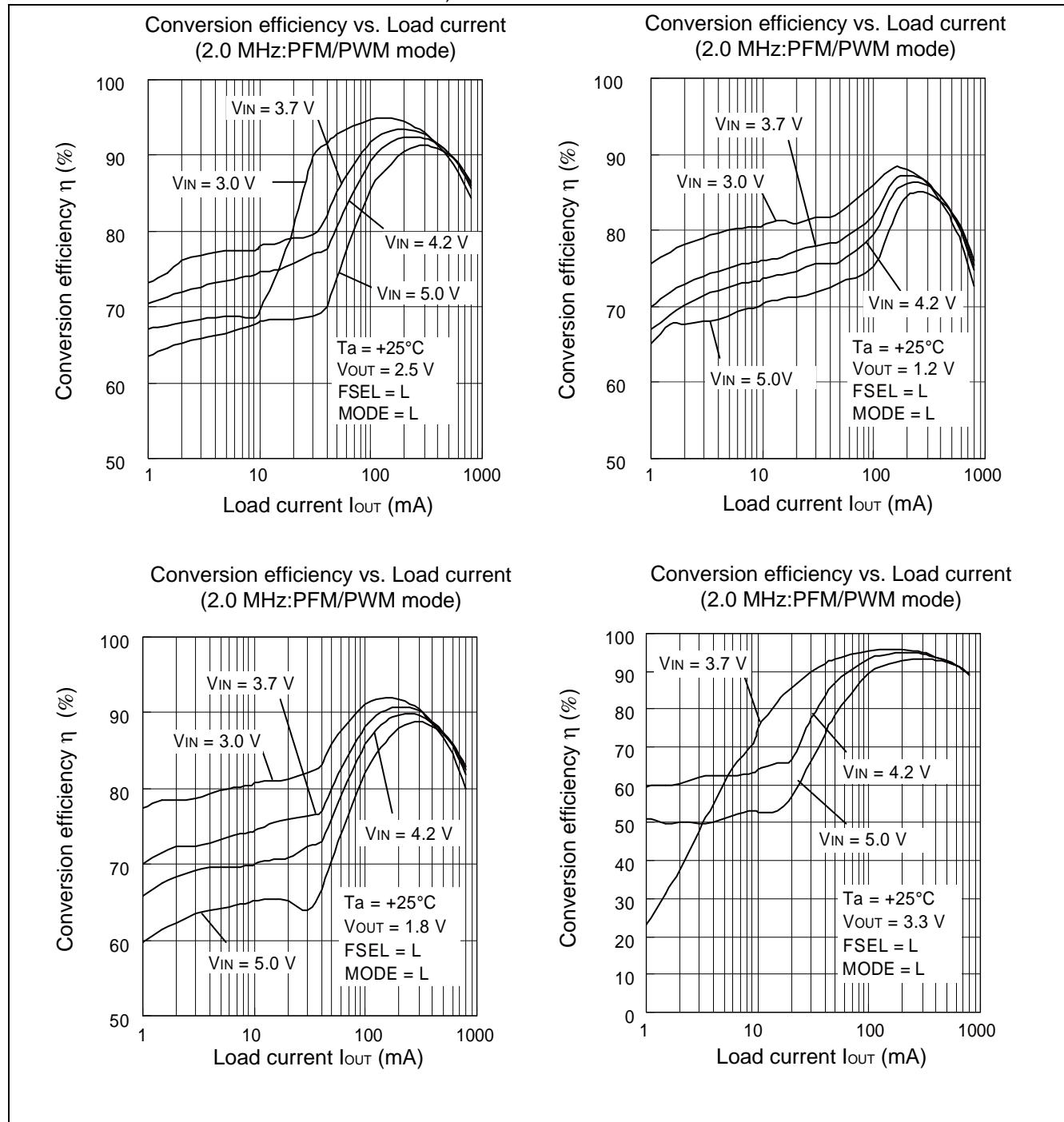
- The switching operation of the MB39C006A works by monitoring and controlling the peak current which, incidentally, serves as form of short-circuit protection. However, do not leave the output short-circuited for long periods of time. If the output is short-circuited where  $V_{IN} < 2.9$  V, the current limit value (peak current to the inductor) tends to rise. Leaving in the short-circuit state, the temperature of the MB39C006A will continue rising and activate the thermal protection.

Once the thermal protection stops the output, the temperature of the IC will go down and operation will resume, after which the output will repeat the starting and stopping.

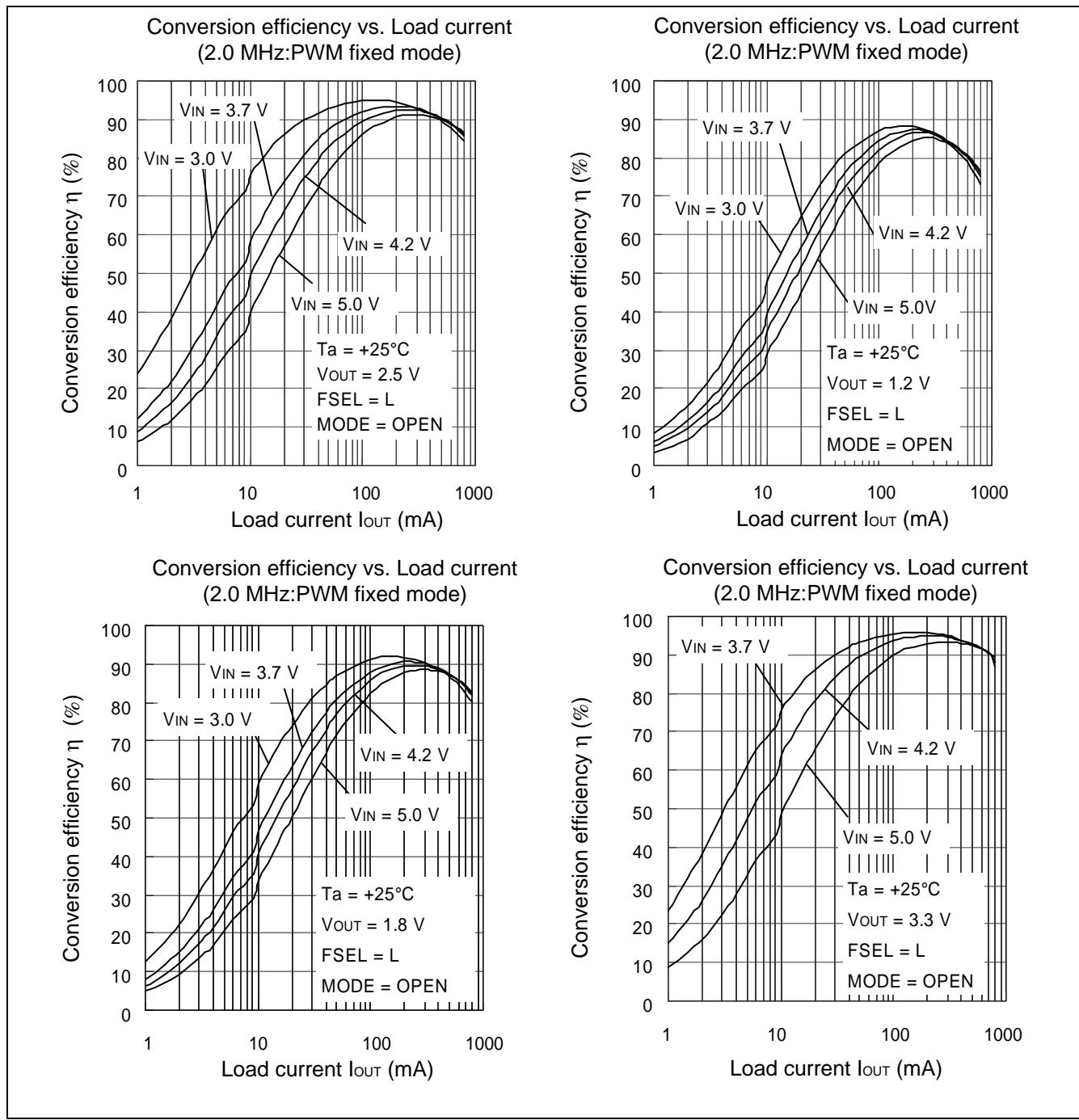
Although this effect will not destroy the IC, the thermal exposure to the IC over prolonged hours may affect the peripherals surrounding it.

## ■ EXAMPLE OF STANDARD OPERATION CHARACTERISTICS

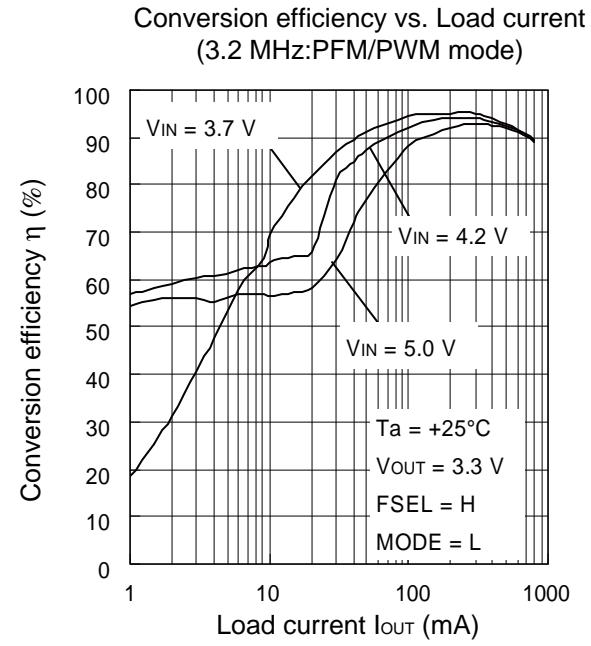
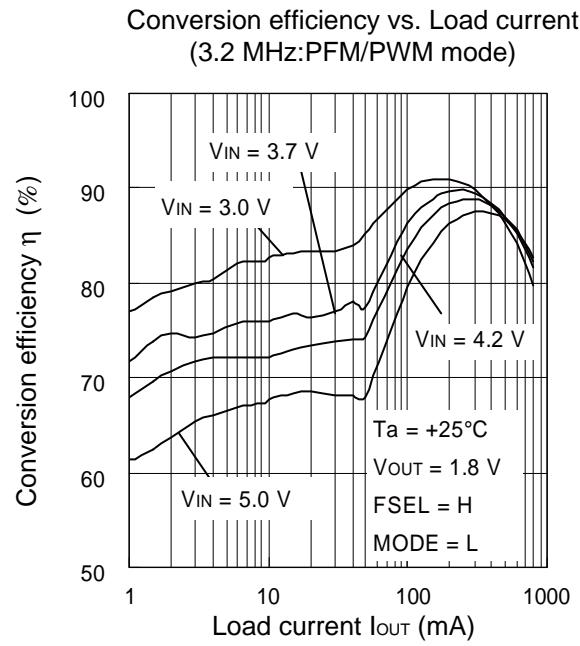
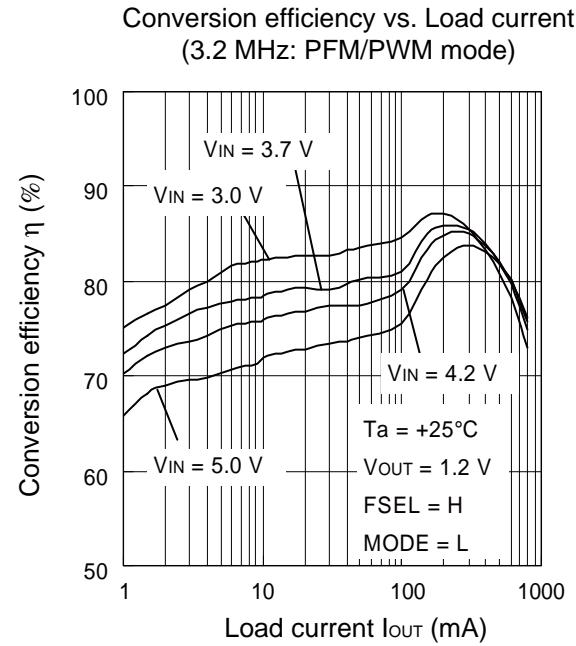
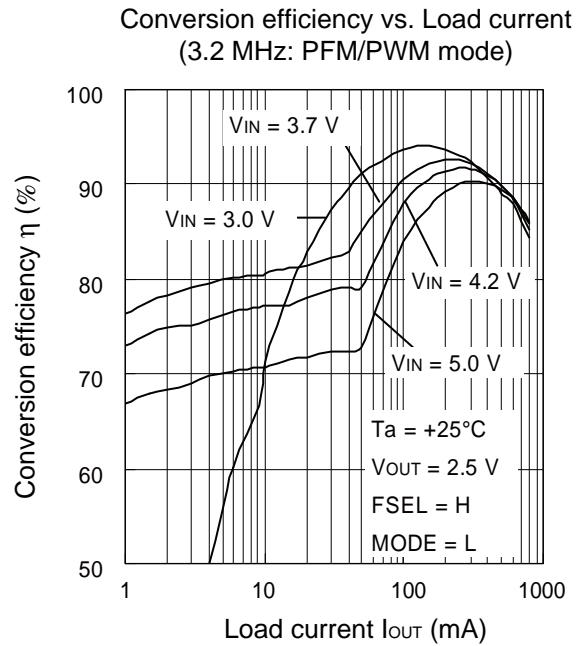
(Shown below is an example of characteristics for connection according to "■ TEST CIRCUIT FOR MEASURING TYPICAL OPERATING CHARACTERISTICS".)



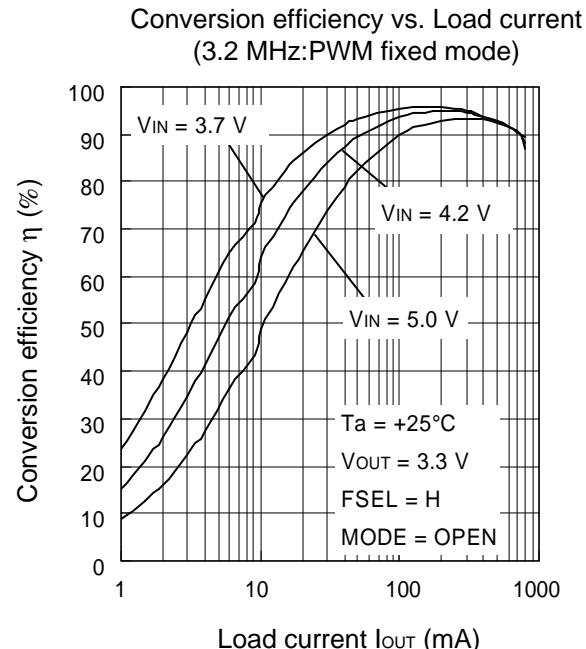
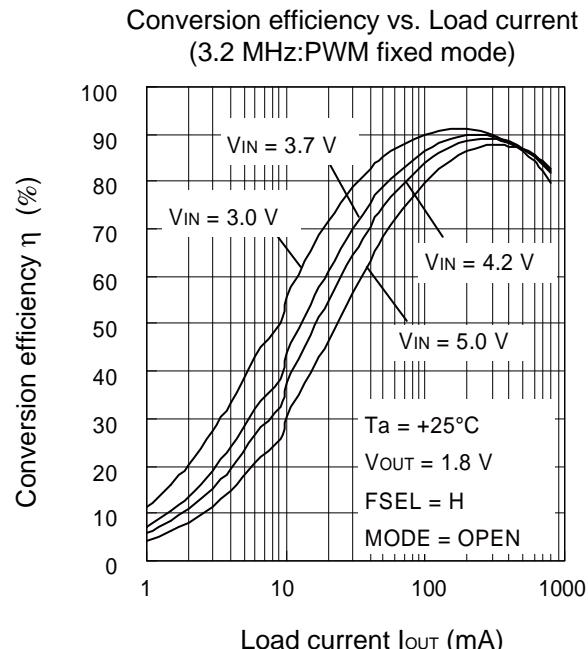
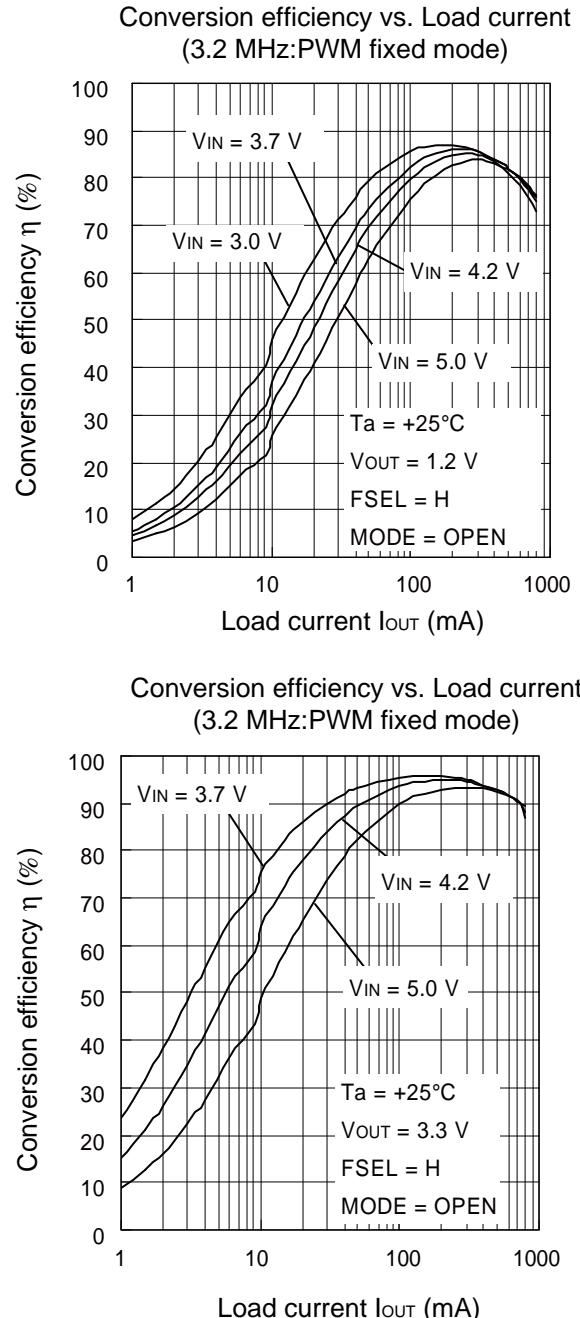
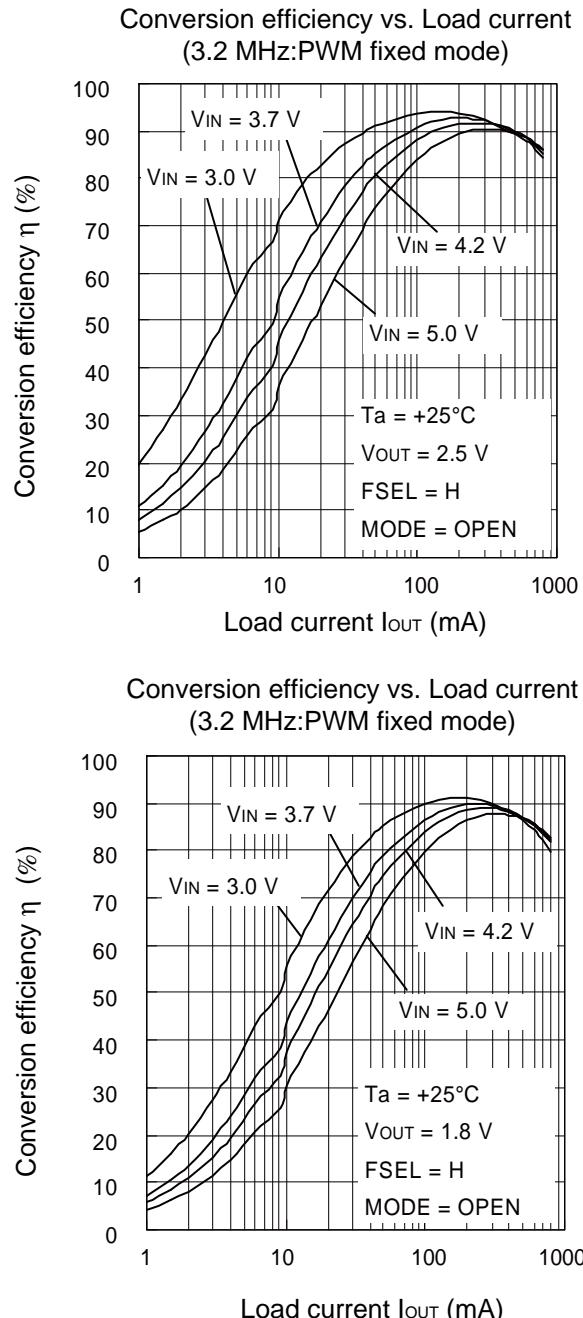
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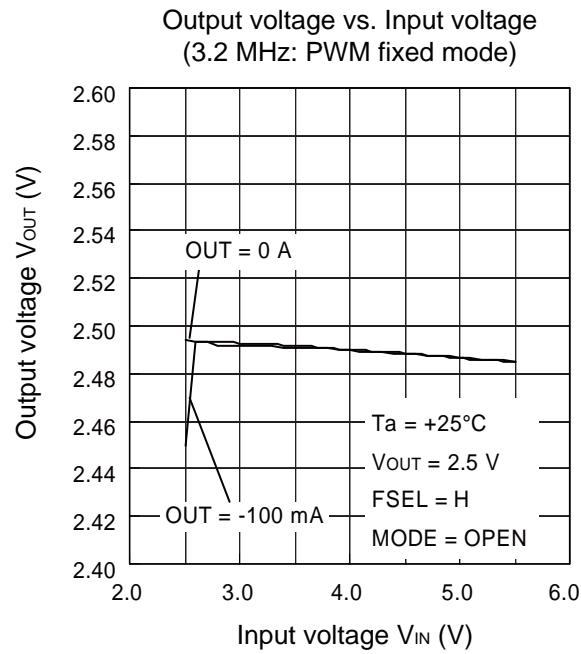
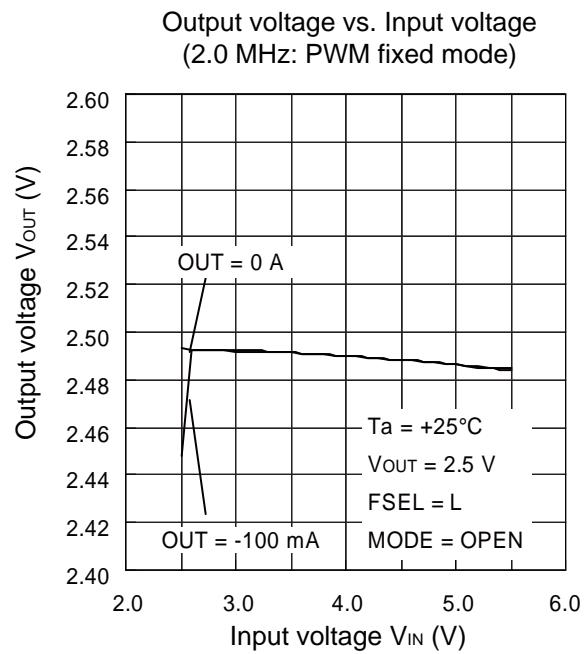
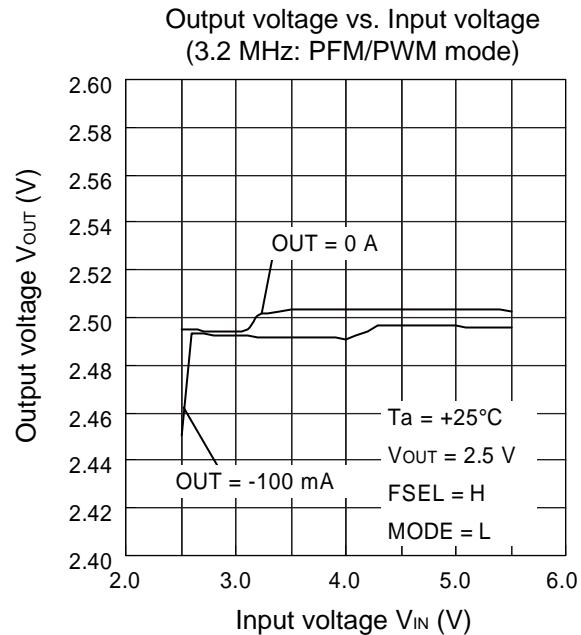
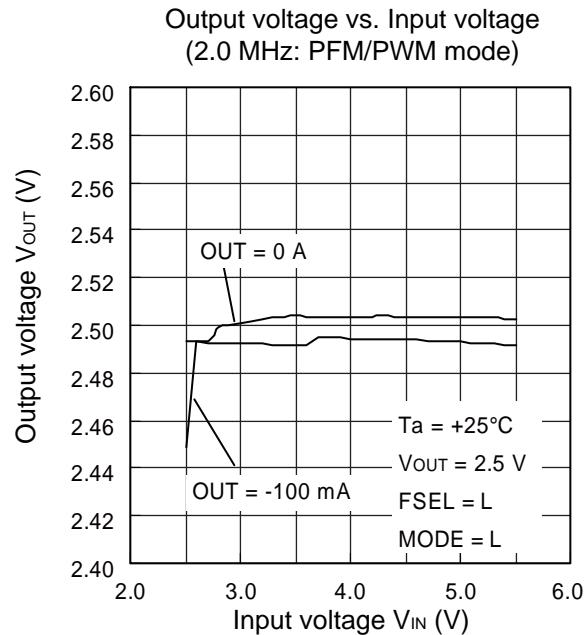


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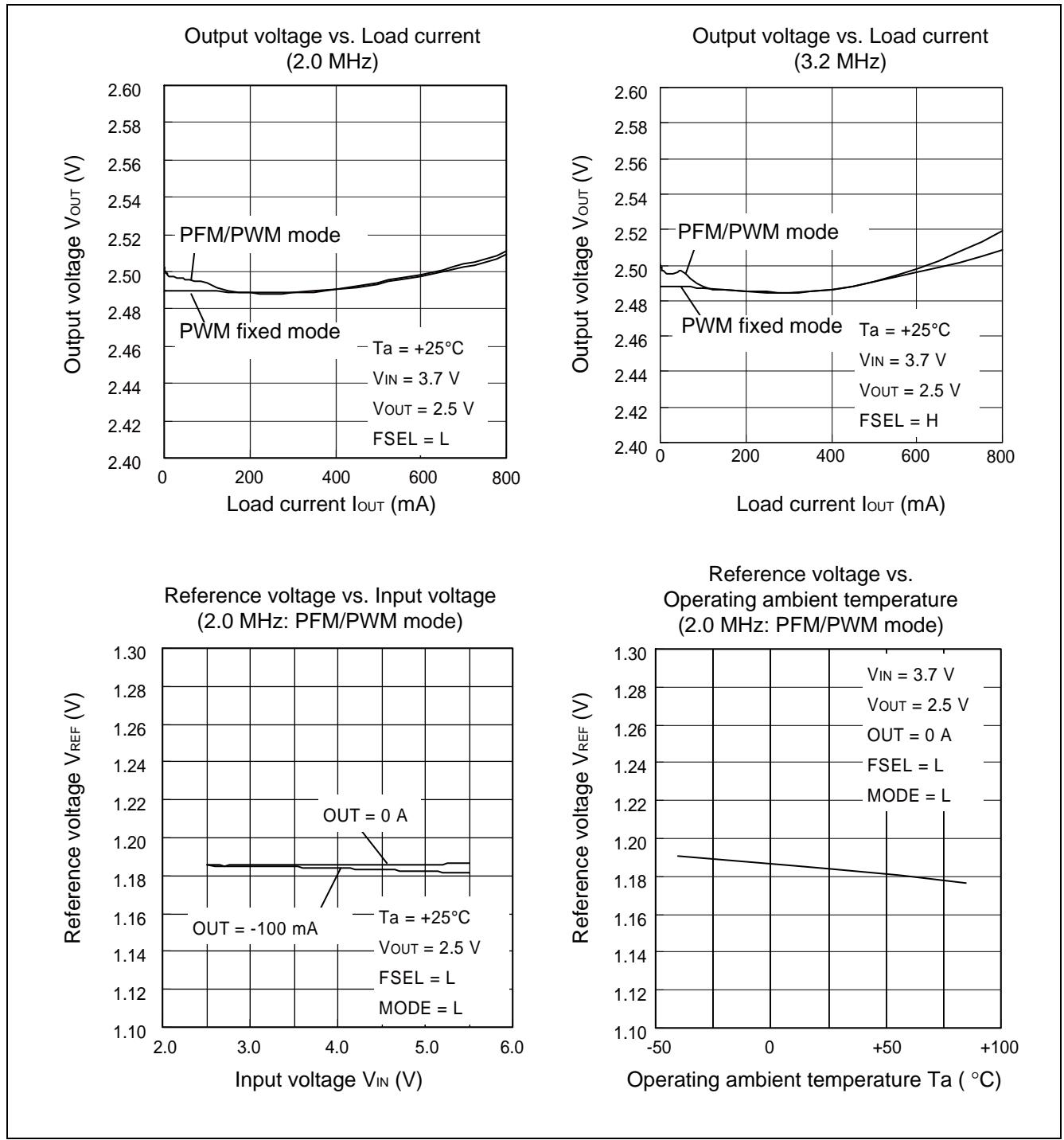


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# MB39C006A

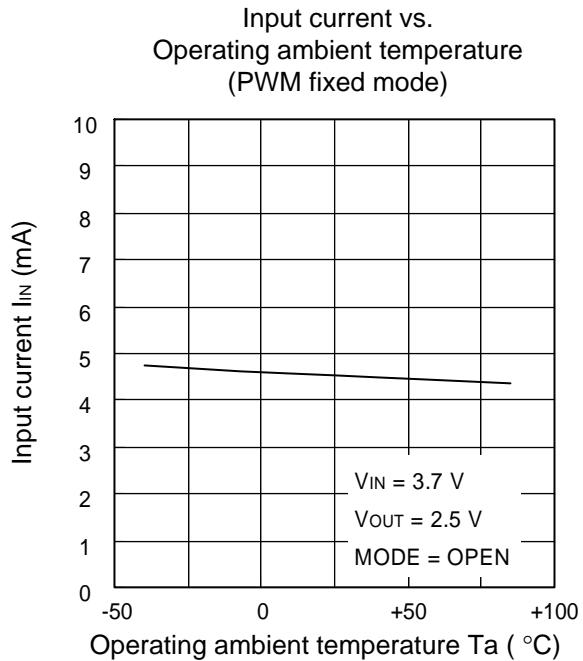
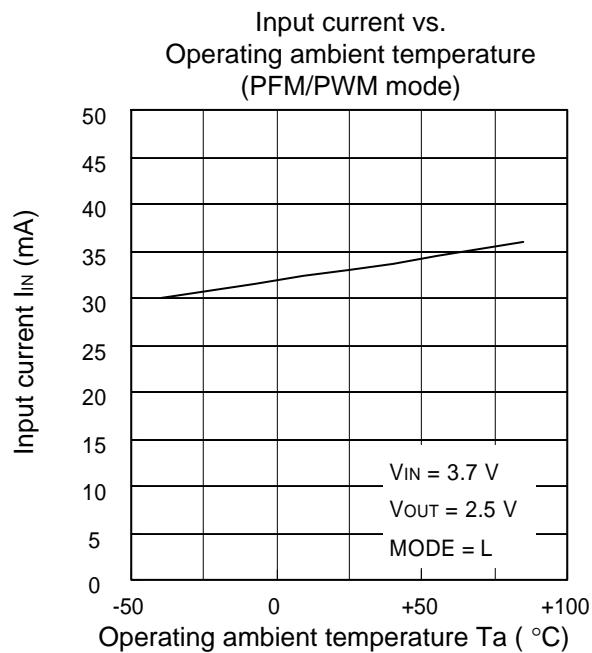
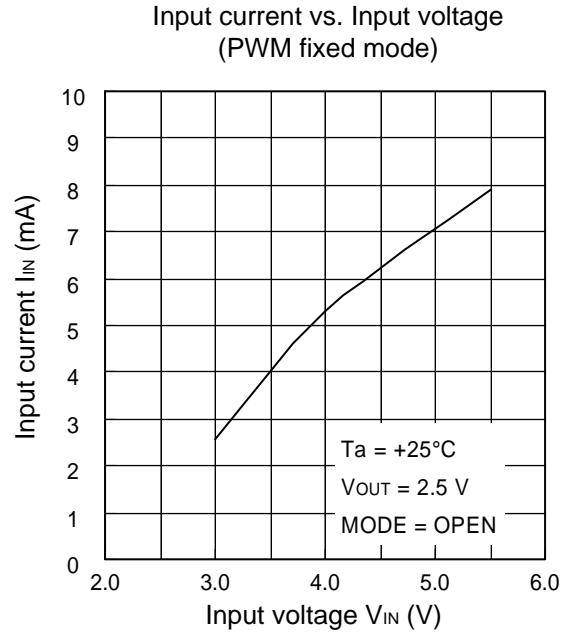
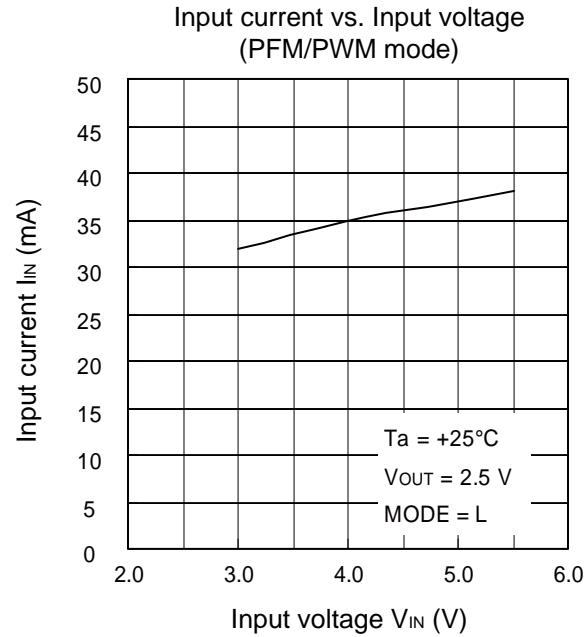


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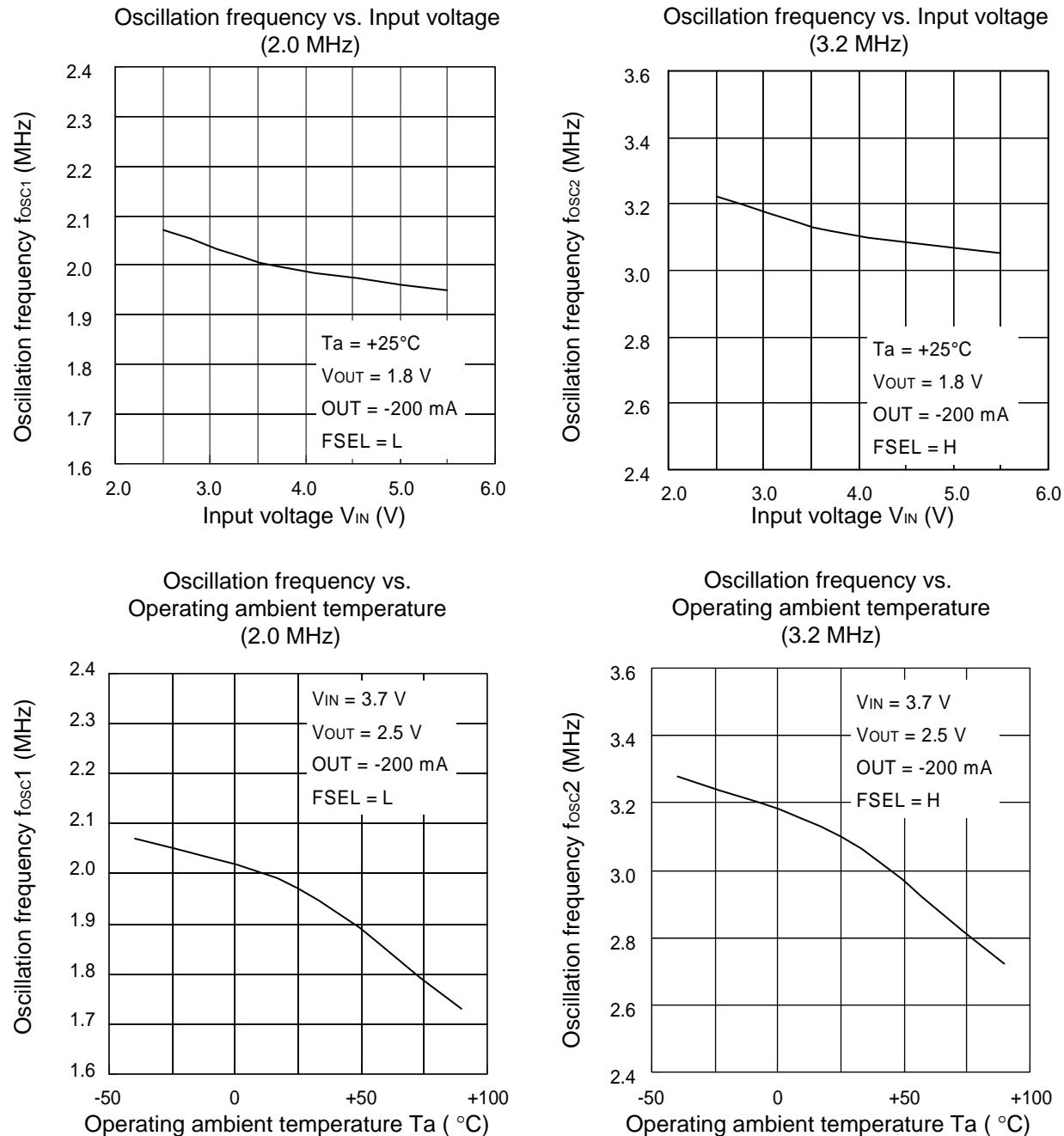


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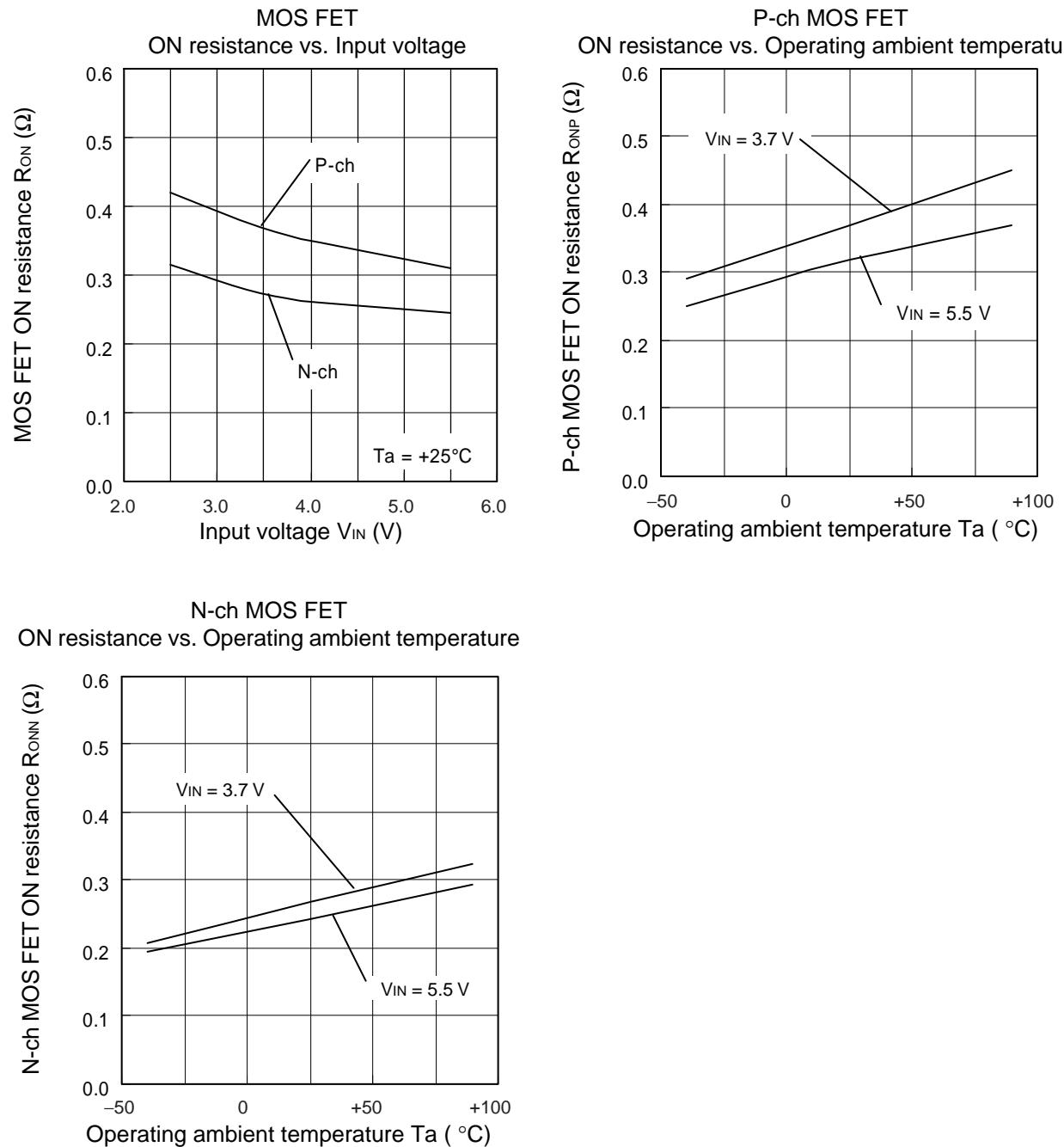
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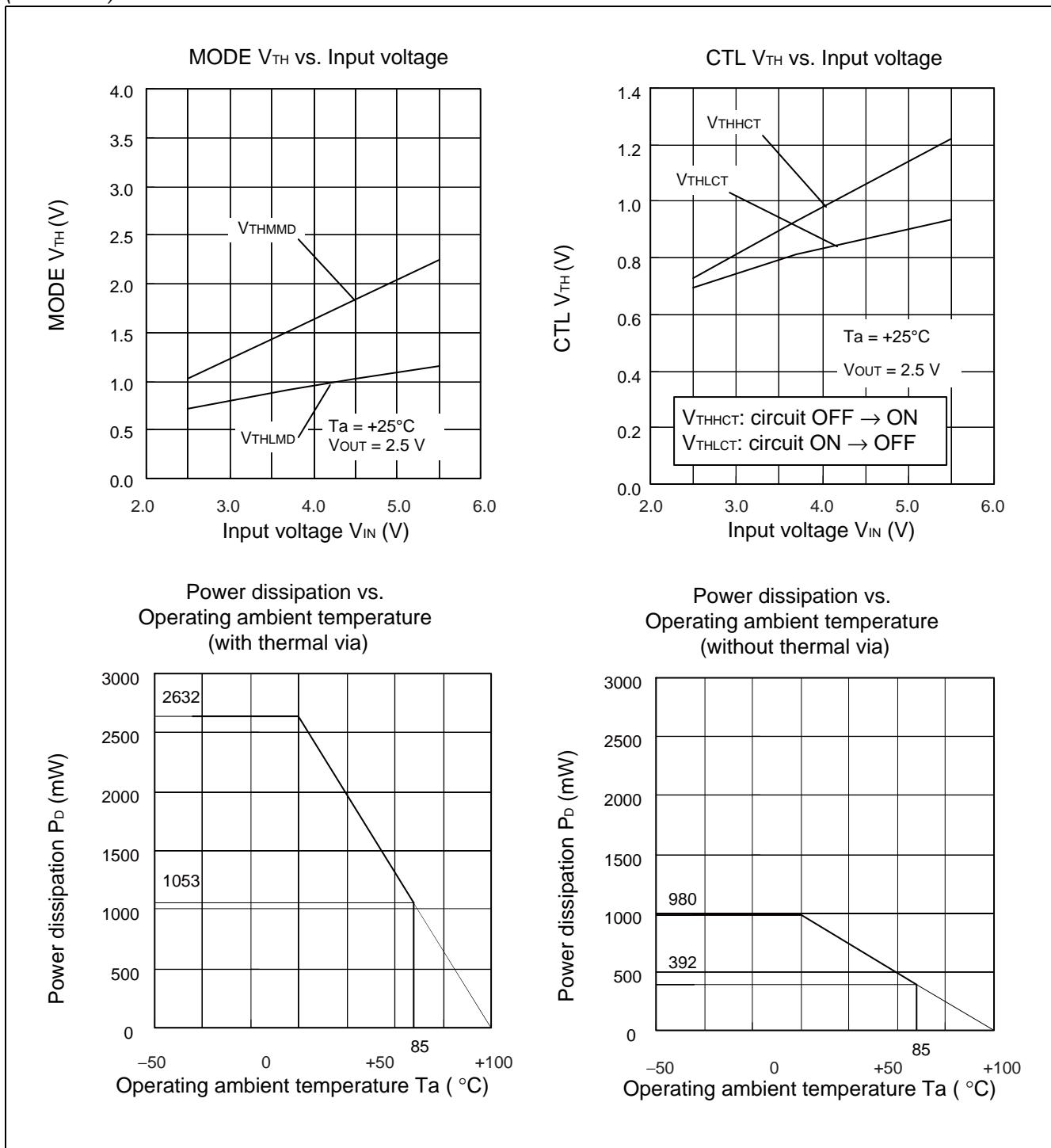


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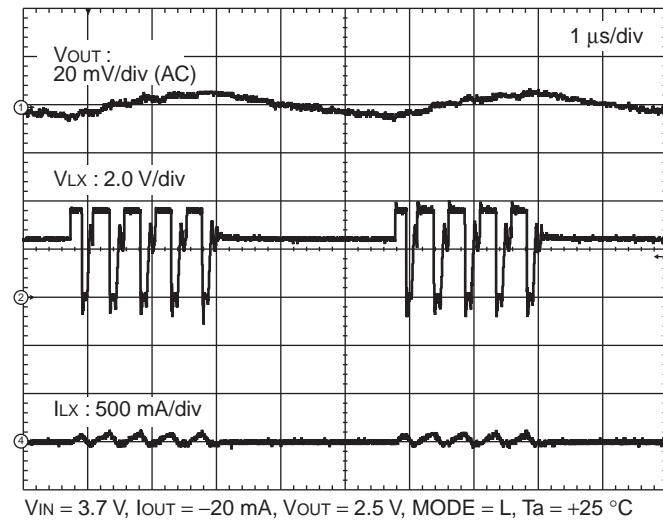
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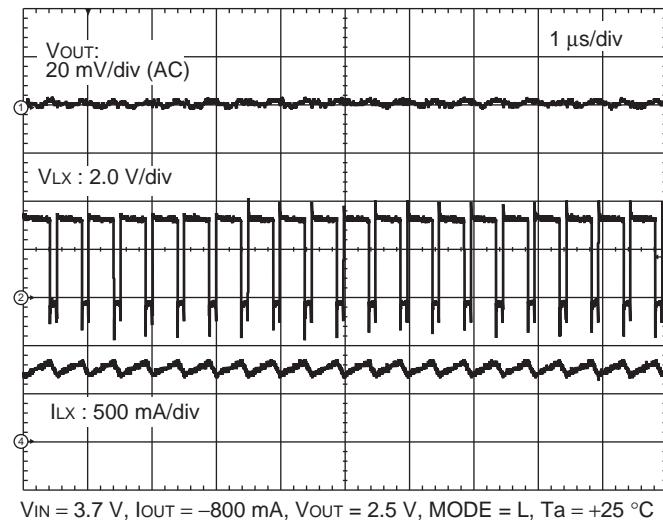
# MB39C006A

- Switching waveforms

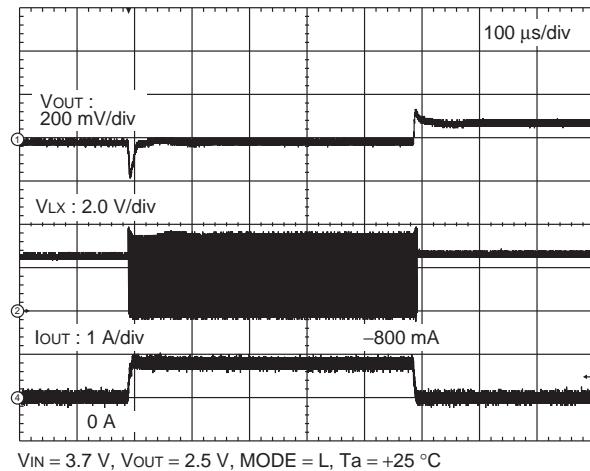
- PFM/PWM operation



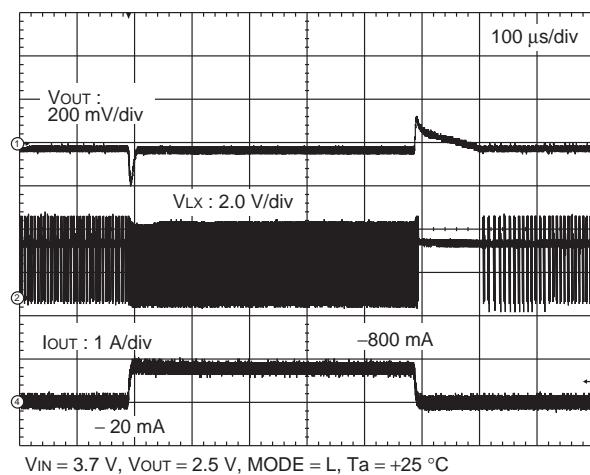
- PWM operation



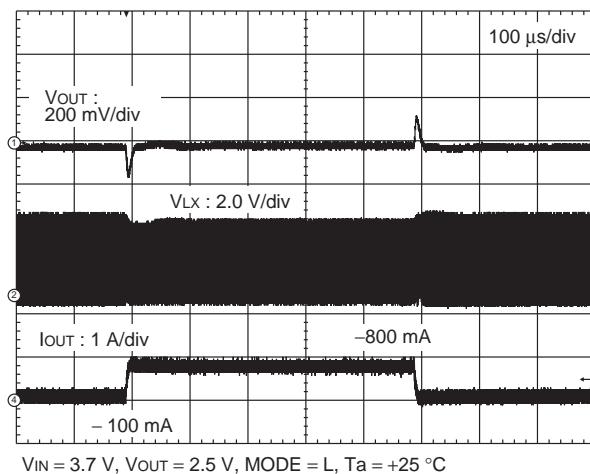
- Output waveforms at sudden load changes (0 A  $\leftrightarrow$  - 800 mA)



- Output waveforms at sudden load changes (- 20 mA  $\leftrightarrow$  - 800 mA)



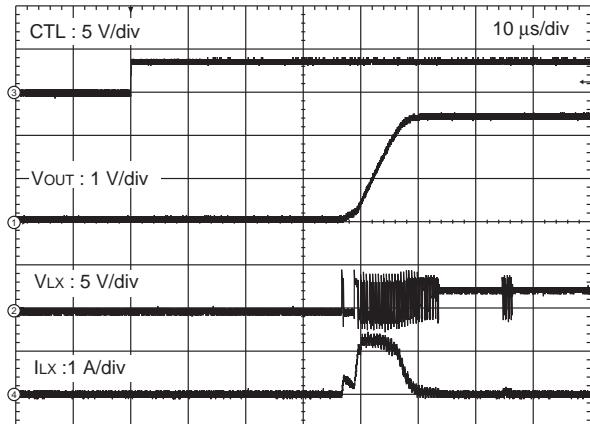
- Output waveforms at sudden load changes (- 100 mA  $\leftrightarrow$  - 800 mA)



# MB39C006A

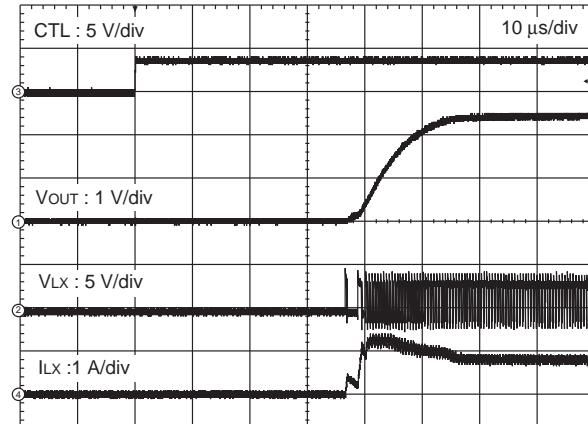
- CTL start-up waveform

(No load, No VREFIN capacitor)



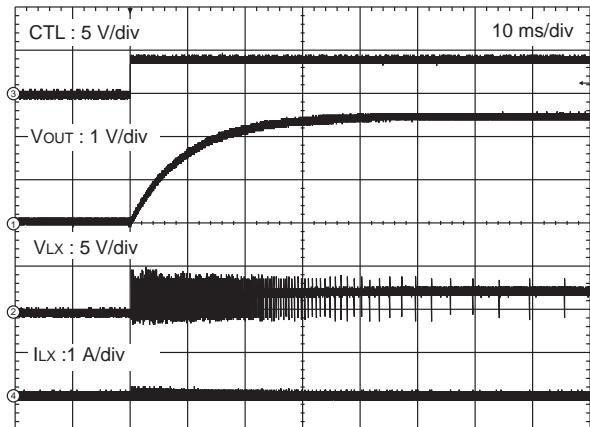
VIN = 3.7 V, IOUT = 0 A, VOUT = 2.5 V, MODE = L, Ta = +25 °C

(Maximum load, No VREFIN capacitor)



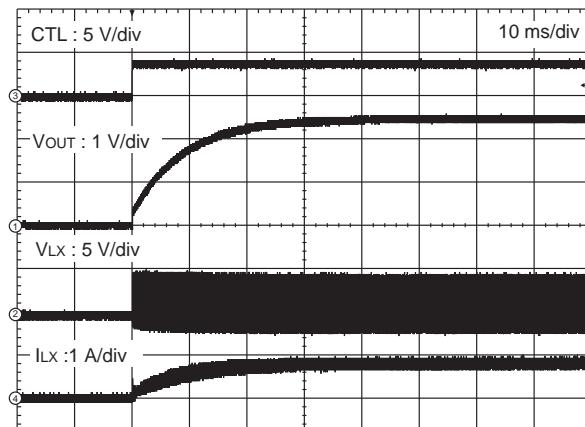
VIN = 3.7 V, IOUT = -800 mA, (3.125 Ω) VOUT = 2.5 V, MODE = L, Ta = +25 °C

(No load, VREFIN capacitor = 0.1 μF)



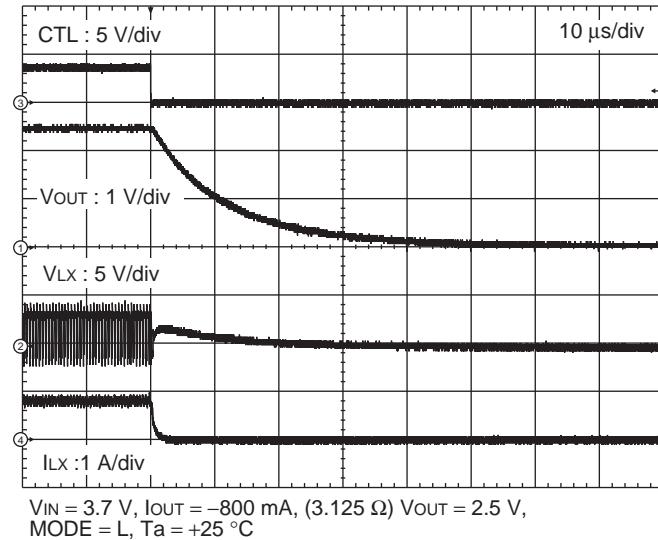
VIN = 3.7 V, IOUT = 0 A, VOUT = 2.5 V, MODE = L, Ta = +25 °C

(Maximum load, VREFIN capacitor = 0.1 μF)

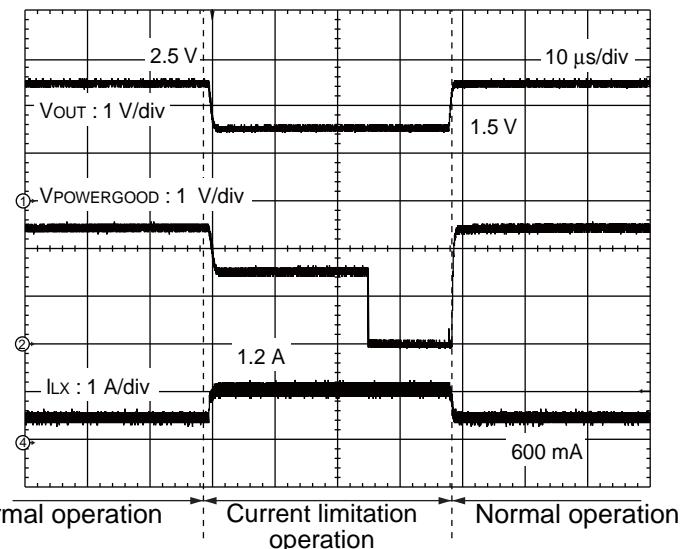


VIN = 3.7 V, IOUT = -800 mA, (3.125 Ω) VOUT = 2.5 V, MODE = L, Ta = +25 °C

- CTL stop waveform (No load, VREFIN capacitor = 0.1  $\mu$ F)

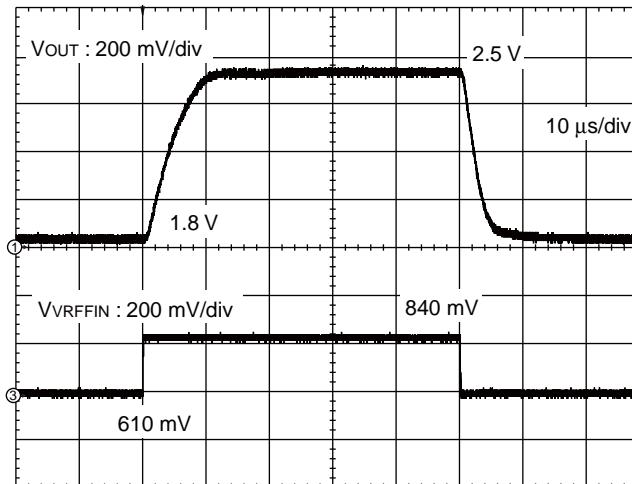


- Current limitation waveform



# MB39C006A

- Waveform of dynamic output voltage transition ( $V_{O1}$  1.8 V  $\leftrightarrow$  2.5 V)

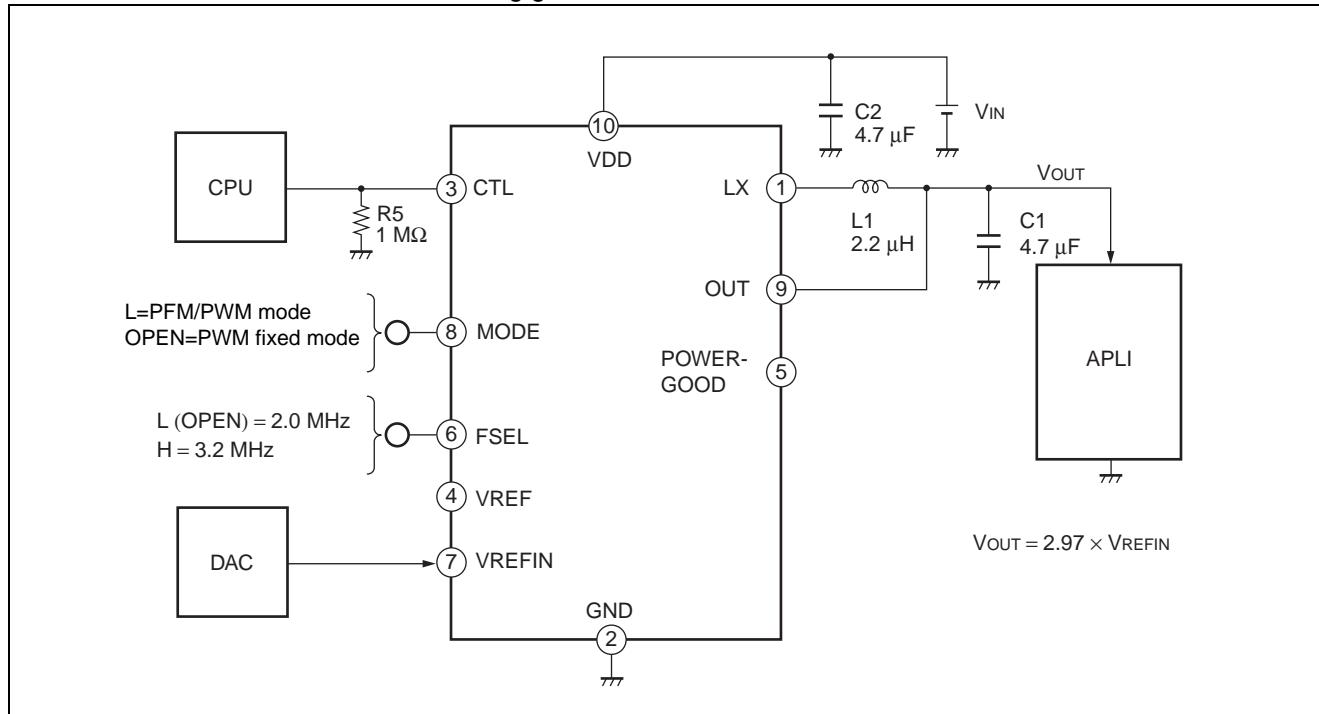


$V_{IN} = 3.7$  V,  $I_{O1} = -800$  mA,  $-576$  mA (3.125  $\Omega$ ), MODE = L,  $T_a = +25$  °C, No VREFIN Capacitor

## ■ APPLICATION CIRCUIT EXAMPLES

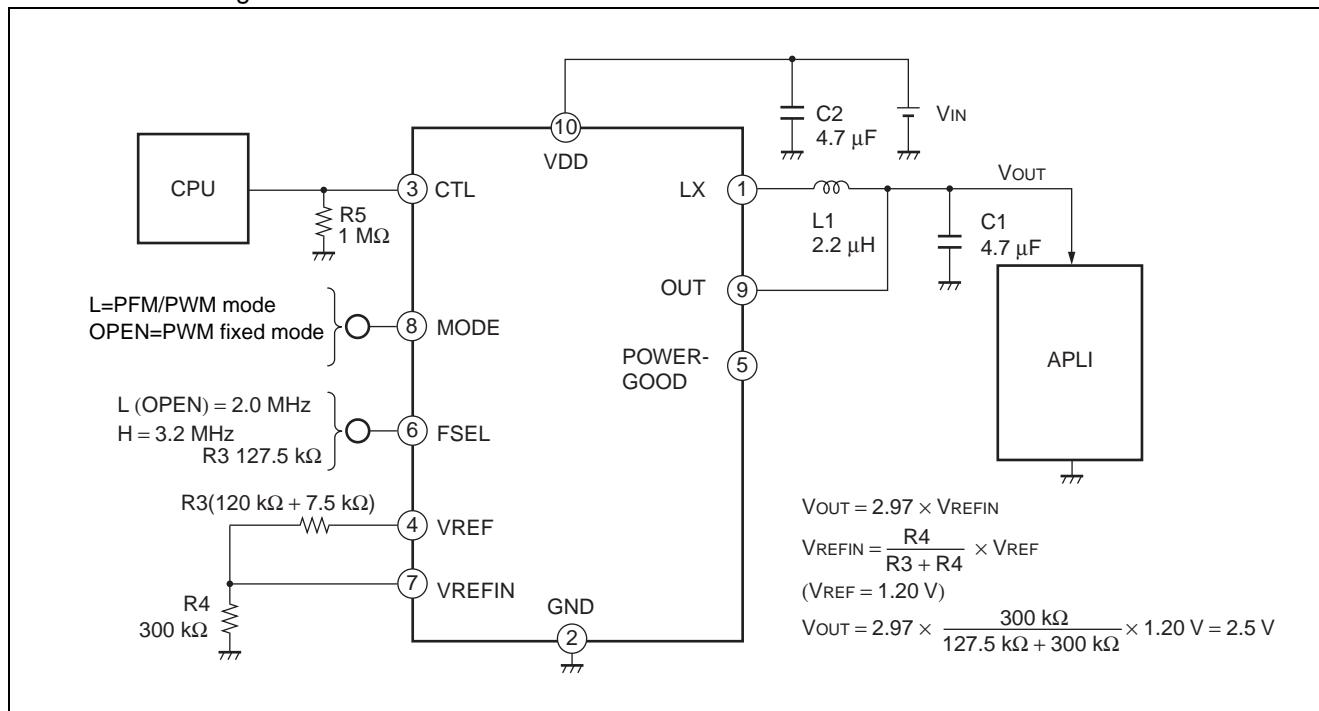
### • APPLICATION CIRCUIT EXAMPLE 1

- An external voltage is input to the reference voltage external input (VREFIN) , and the V<sub>OUT</sub> voltage is set to 2.97 times as much as the V<sub>OUT</sub> setting gain.



### • APPLICATION CIRCUIT EXAMPLE 2

- The voltage of VREF pin is input to the reference voltage external input (VREFIN) by the dividing resistors. The V<sub>OUT</sub> voltage is set to 2.5 V.



# MB39C006A

- Application Circuit Example Components List

| Component | Item              | Part Number                                                | Specification                     | Package      | Vendor |
|-----------|-------------------|------------------------------------------------------------|-----------------------------------|--------------|--------|
| L1        | Inductor          | VLF4012AT-2R2M                                             | 2.2 $\mu$ H, RDC = 76 m $\Omega$  | SMD          | TDK    |
|           |                   | MIPW3226D2R2M                                              | 2.2 $\mu$ H, RDC = 100 m $\Omega$ | SMD          | FDK    |
| C1        | Ceramic capacitor | C2012JB1A475K                                              | 4.7 $\mu$ F (10 V)                | 2012         | TDK    |
| C2        | Ceramic capacitor | C2012JB1A475K                                              | 4.7 $\mu$ F (10 V)                | 2012         | TDK    |
| R3        | Resistor          | RK73G1JTTD D 7.5 k $\Omega$<br>RK73G1JTTD D 120 k $\Omega$ | 7.5 k $\Omega$<br>120 k $\Omega$  | 1608<br>1608 | KOA    |
| R4        | Resistor          | RK73G1JTTD D 300 k $\Omega$                                | 300 k $\Omega$                    | 1608         | KOA    |
| R5        | Resistor          | RK73G1JTTD D                                               | 1 M $\Omega$ $\pm$ 0.5%           | 1608         | KOA    |

TDK : TDK Corporation

FDK : FDK Corporation

KOA : KOA Corporation

## ■ USAGE PRECAUTIONS

### 1. Do not configure the IC over the maximum ratings

If the IC is used over the maximum ratings, the LSI may be permanently damaged.

It is preferable for the device to normally operate within the recommended usage conditions. Usage outside of these conditions can adversely affect reliability of the LSI.

### 2. Use the devices within recommended operating conditions

The recommended operating conditions are the conditions under which the LSI is guaranteed to operate.

The electrical ratings are guaranteed when the device is used within the recommended operating conditions and under the conditions stated for each item.

### 3. Printed circuit board ground lines should be set up with consideration for common impedance

### 4. Take appropriate static electricity measures.

- Containers for semiconductor materials should have anti-static protection or be made of conductive material.
- After mounting, printed circuit boards should be stored and shipped in conductive bags or containers.
- Work platforms, tools, and instruments should be properly grounded.
- Working personnel should be grounded with resistance of 250 kΩ to 1 MΩ between body and ground.

### 5. Do not apply negative voltages.

The use of negative voltages below – 0.3 V may create parasitic transistors on LSI lines, which can cause abnormal operation.

## ■ ORDERING INFORMATION

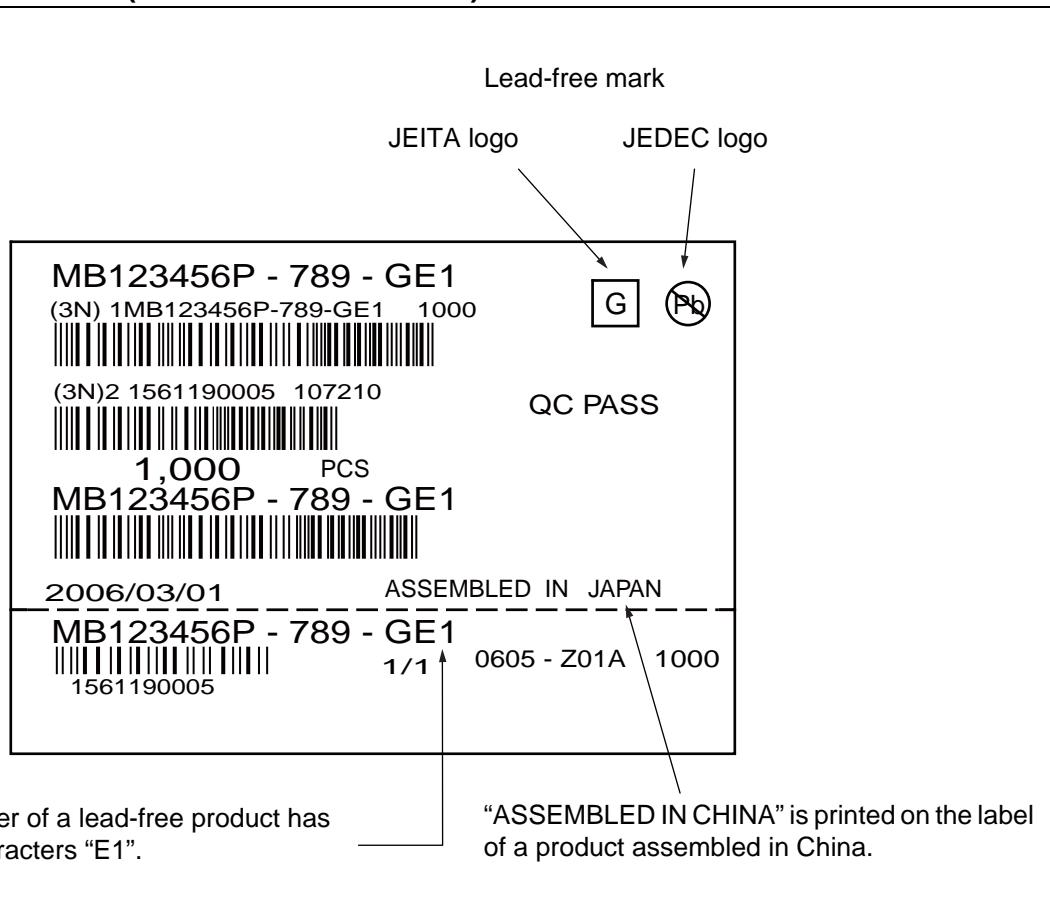
| Part number | Package                             | Remarks |
|-------------|-------------------------------------|---------|
| MB39C006APN | 10-pin plastic SON<br>(LCC-10P-M04) |         |

## ■ RoHS COMPLIANCE INFORMATION OF LEAD (Pb) FREE VERSION

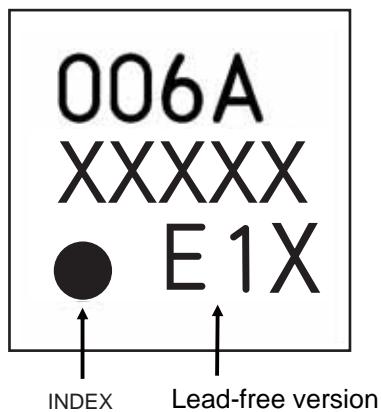
The LSI products of FUJITSU MICROELECTRONICS with "E1" are compliant with RoHS Directive, and has observed the standard of lead, cadmium, mercury, hexavalent chromium, polybrominated biphenyls (PBB), and polybrominated diphenylethers (PBDE).

A product whose part number has trailing characters "E1" is RoHS compliant.

## ■ LABELING SAMPLE (LEAD FREE VERSION)



## ■ MARKING FORMAT



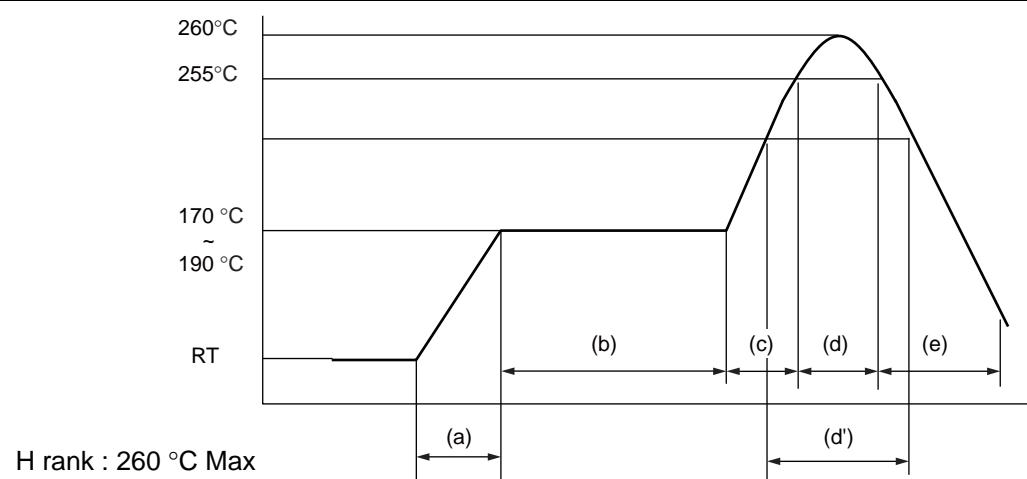
## ■ RECOMMENDED MOUNTING CONDITIONS of MB39C006APN

[FUJITSU MICROELECTRONICS Recommended Mounting Conditions]

| Item               | Condition                                                   |                                                   |
|--------------------|-------------------------------------------------------------|---------------------------------------------------|
| Mounting Method    | IR (infrared reflow), warm air reflow                       |                                                   |
| Mounting times     | 2 times                                                     |                                                   |
| Storage period     | Before opening                                              | Please use it within two years after manufacture. |
|                    | From opening to the 2nd reflow                              |                                                   |
| Storage conditions | 5 °C to 30 °C, 70%RH or less (the lowest possible humidity) |                                                   |

### [Parameters for Each Mounting Method]

#### IR (infrared reflow)



- (a) Temperature Increase gradient : Average 1 °C/s to 4 °C/s
- (b) Preliminary heating : Temperature 170 °C to 190 °C, 60s to 180s
- (c) Temperature Increase gradient : Average 1 °C/s to 4 °C/s
- (d) Actual heating : Temperature 260 °C Max; 255 °C or more, 10s or less
- (d') : Temperature 230 °C or more, 40s or less  
or  
Temperature 225 °C or more, 60s or less  
or  
Temperature 220 °C or more, 80s or less
- (e) Cooling : Natural cooling or forced cooling

Note : Temperature : the top of the package body

# MB39C006A

## ■ EVALUATION BOARD SPECIFICATION

The MB39C006A Evaluation Board provides the proper environment for evaluating the efficiency and other characteristics of the MB39C006A.

- Terminal information

| Symbol    | Functions                                                                                                                                                                                                                                                                                                       |
|-----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| VIN       | Power supply terminal.<br>In standard condition 3.1 V to 5.5 V*.<br>* When the VIN/VOUT difference is to be held within 0.6 V or less, such as for devices with a standard output voltage (VOUT = 2.5 V) and VIN < 3.1 V, FUJITSU MICROELECTRONICS recommends to change the output capacity (C1) to 10 $\mu$ F. |
| VOUT      | Output terminal.                                                                                                                                                                                                                                                                                                |
| VCTL      | Power supply terminal for setting the CTL terminal.<br>Use this terminal by connecting with VIN (When SW is mounted).                                                                                                                                                                                           |
| CTL       | Direct supply terminal of CTL.<br>CTL = 0 V to 0.80 V (Typ) : Shutdown<br>CTL = 0.95 V (Typ) to VIN : Normal operation                                                                                                                                                                                          |
| MODE      | Direct supply terminal of MODE.<br>MODE = 0 V to 0.4 V (Max) : PFM/PWM mode<br>MODE = OPEN (Remove R6) : PWM mode                                                                                                                                                                                               |
| VREF      | Reference voltage output terminal.<br>$V_{REF} = 1.20$ V (Typ)                                                                                                                                                                                                                                                  |
| VREFIN    | External reference voltage input terminal.<br>When an external reference voltage is supplied, connect to this terminal.                                                                                                                                                                                         |
| FSEL      | Operating frequency range setting terminal.<br>FSEL = 0 V : 2.0 MHz operation<br>FSEL = VIN : 3.2 MHz operation*<br>* FUJITSU MICROELECTRONICS recommends to change the inductor to 1.5 $\mu$ H.                                                                                                                |
| POWERGOOD | POWERGOOD output terminal.<br>"High" level output when OUT voltage reaches 97% or more of output setting voltage.                                                                                                                                                                                               |
| PGND      | Ground terminal.<br>Connect power supply GND to the PGND terminal next to the VOUT terminal.                                                                                                                                                                                                                    |
| AGND      | Ground terminal.                                                                                                                                                                                                                                                                                                |

- Startup terminal information

| Terminal name | Condition                      | Functions                                                                          |
|---------------|--------------------------------|------------------------------------------------------------------------------------|
| CTL           | L : Open<br>H : Connect to VIN | ON/OFF switch for the IC.<br>L : Shutdown<br>H : Normal operation                  |
| FSEL          | L : Open<br>H : Connect to VIN | Setting switch of FSEL terminal.<br>L : 2.0 MHz operation<br>H : 3.2 MHz operation |

- Jumper information

| JP  | Functions                           |
|-----|-------------------------------------|
| JP1 | Normally used shorted (0 $\Omega$ ) |
| JP2 | Not mounted                         |

- Setup and checkup

(1) Setup

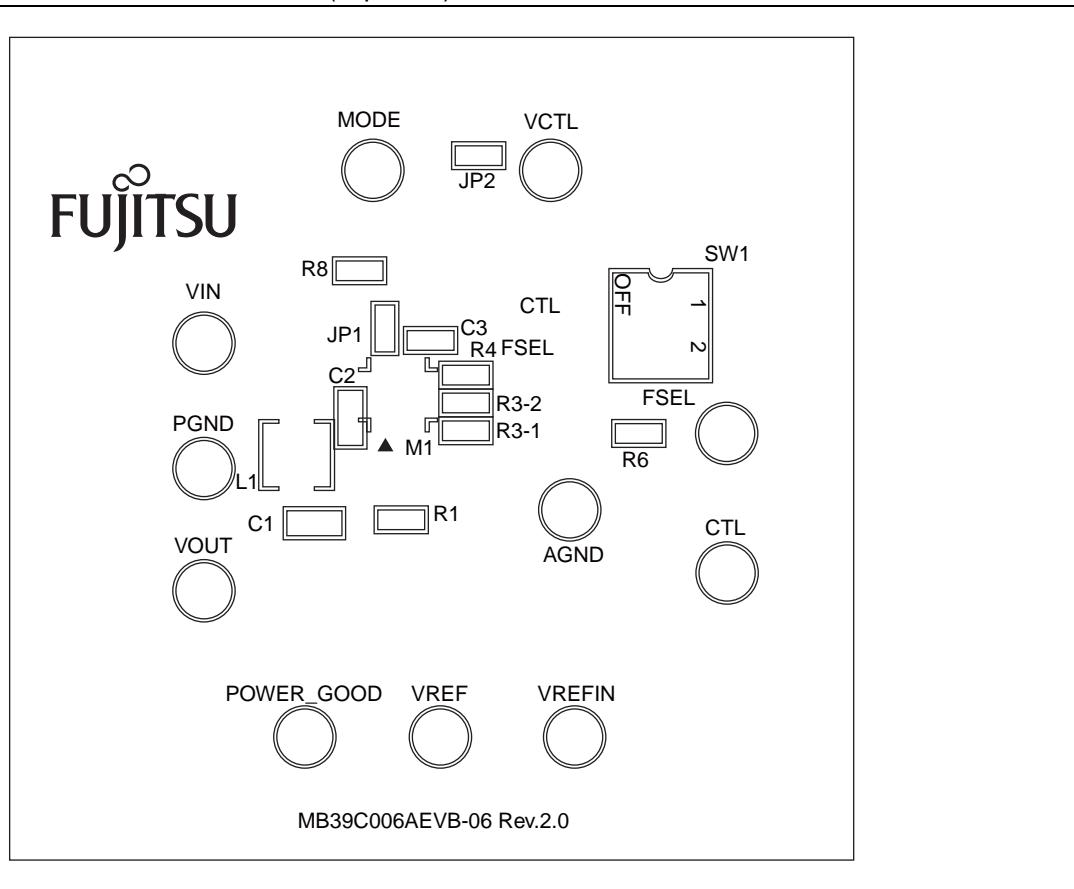
(1) -1. Connect the CTL terminal to the VIN terminal.

(1) -2. Connect the power supply terminal to the VIN terminal, and the power supply GND terminal to the PGND terminal. (Example of setting power supply voltage : 3.7 V)

(2) Checkup

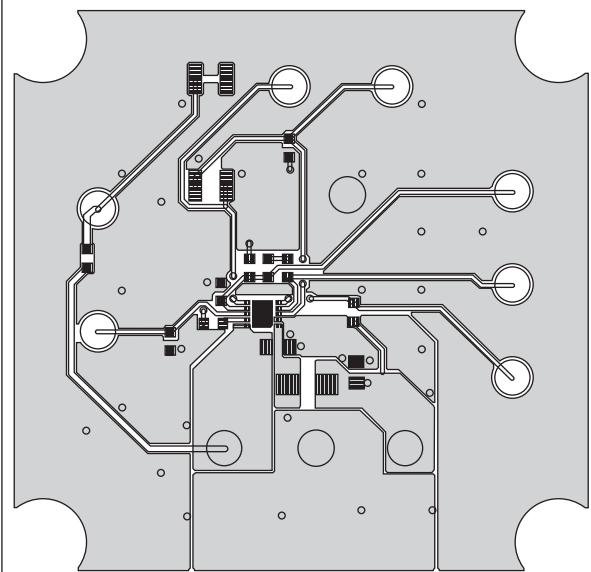
Supply power to VIN. The IC is operating normally if VOUT = 2.5 V (Typ).

- Component layout on the evaluation board (Top View)

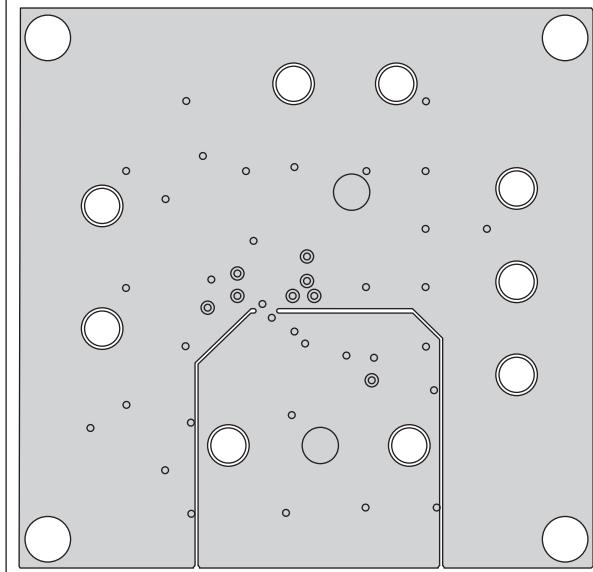


# MB39C006A

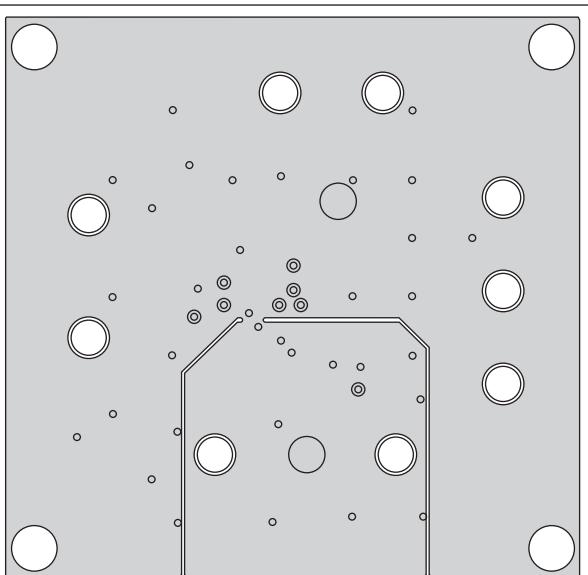
- Evaluation board layout (Top View)



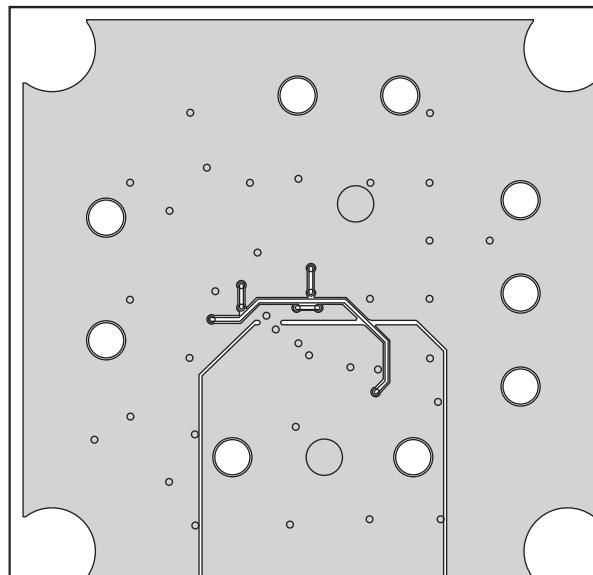
Top Side (Layer1)



Inner Side (Layer2)

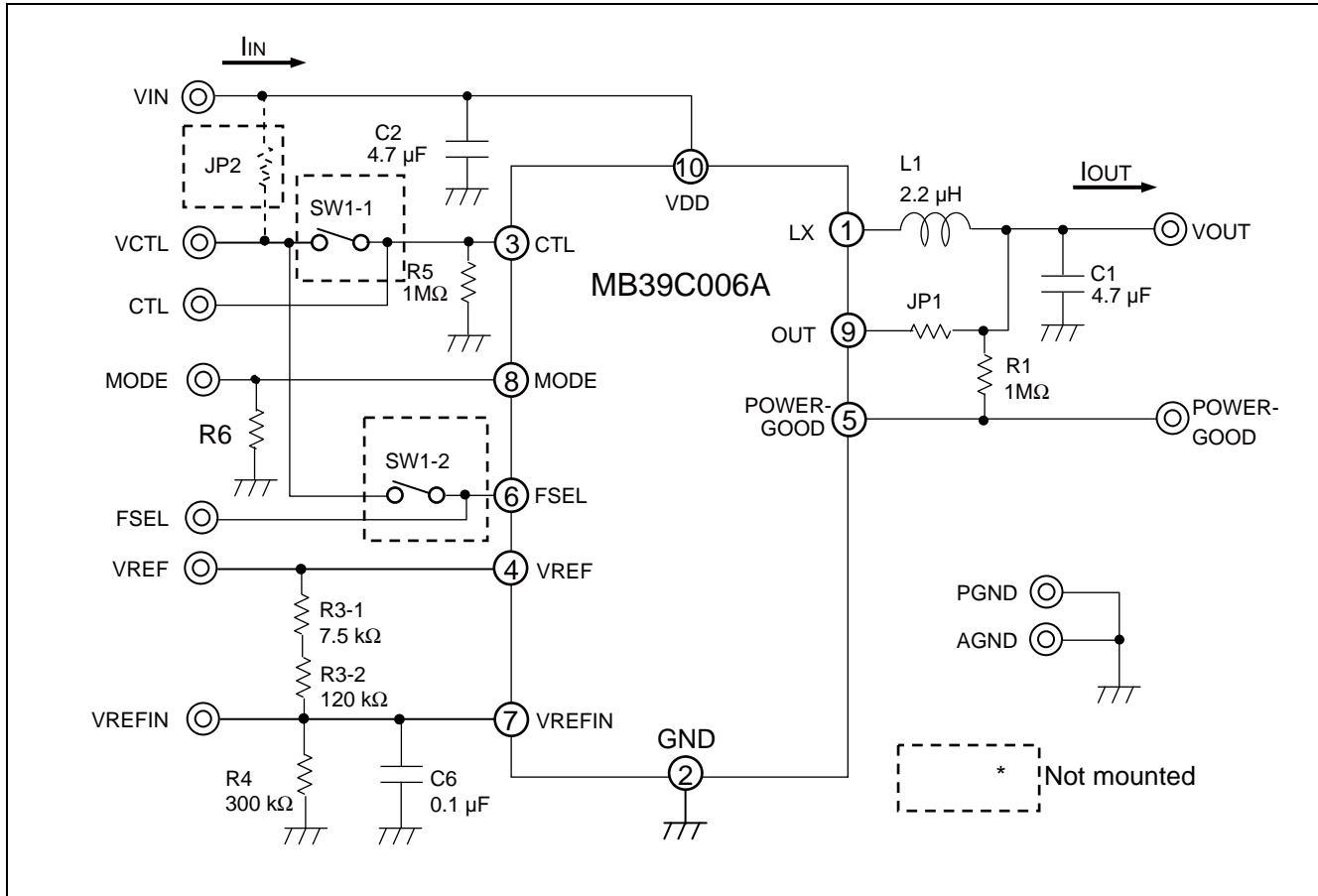


Inner Side (Layer 3)



Bottom Side (Layer 4)

- Connection diagram



# MB39C006A

- Component list

| Component | Part Name         | Model Number                 | Specification                     | Package | Vendor | Remark      |
|-----------|-------------------|------------------------------|-----------------------------------|---------|--------|-------------|
| M1        | IC                | MB39C006APN                  | —                                 | SON10   | FML    |             |
| L1        | Inductor          | VLF4012AT-2R2M               | 2.2 $\mu$ H,<br>RDC=76 m $\Omega$ | SMD     | TDK    |             |
| C1        | Ceramic capacitor | C2012JB1A475K                | 4.7 $\mu$ F (10 V)                | 2012    | TDK    |             |
| C2        | Ceramic capacitor | C2012JB1A475K                | 4.7 $\mu$ F (10 V)                | 2012    | TDK    |             |
| C6        | Ceramic capacitor | C1608JB1H104K                | 0.1 $\mu$ F (50 V)                | 1608    | TDK    |             |
| R1        | Resister          | RK73G1JTTD D<br>1 M $\Omega$ | 1 M $\Omega$ $\pm$ 0.5%           | 1608    | KOA    |             |
| R3-1      | Resister          | RR0816P-752-D                | 7.5 k $\Omega$ $\pm$ 0.5%         | 1608    | SSM    |             |
| R3-2      | Resister          | RR0816P-124-D                | 120 k $\Omega$ $\pm$ 0.5%         | 1608    | SSM    |             |
| R4        | Resister          | RR0816P-304-D                | 300 k $\Omega$ $\pm$ 0.5%         | 1608    | SSM    |             |
| R5        | Resister          | RK73G1JTTD D<br>1 M $\Omega$ | 1 M $\Omega$ $\pm$ 0.5%           | 1608    | KOA    |             |
| R6        | Resister          | RK73Z1J                      | 0 $\Omega$ , 1A                   | 1608    | KOA    |             |
| SW1       | DIP switch        | —                            | —                                 | —       | —      | Not mounted |
| JP1       | Jumper            | RK73Z1J                      | 0 $\Omega$ , 1A                   | 1608    | KOA    |             |
| JP2       | Jumper            | —                            | —                                 | —       | —      | Not mounted |

Note : These components are recommended based on the operating tests authorized.

FML : FUJITSU MICROELECTRONICS LIMITED

TDK : TDK Corporation

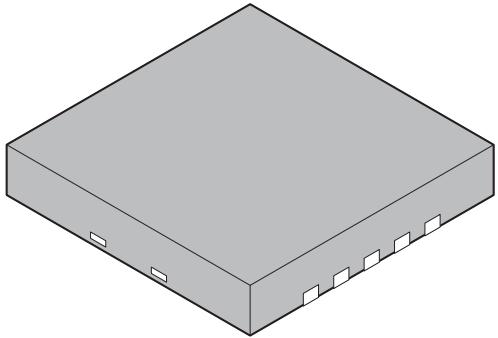
KOA : KOA Corporation

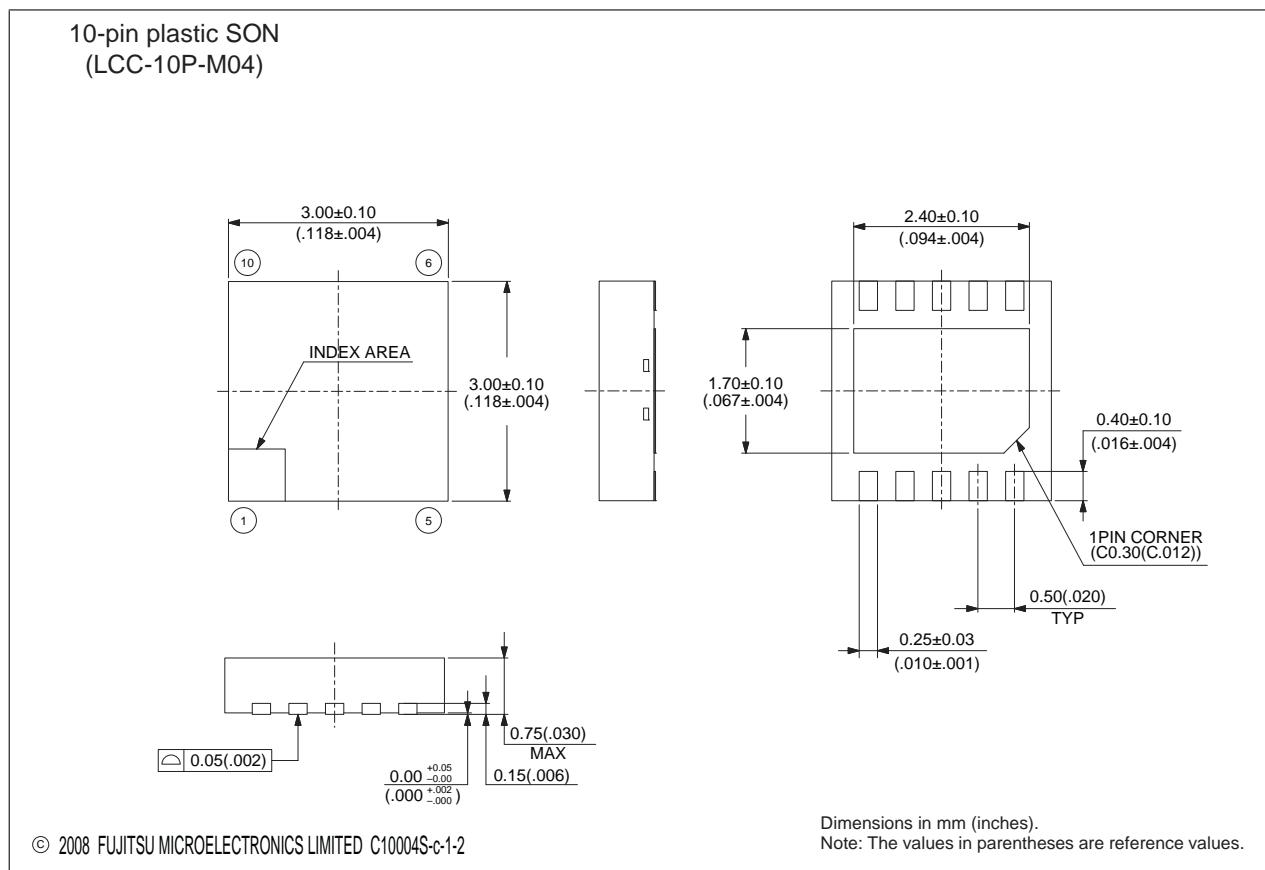
SSM : SUSUMU Co., Ltd

## ■ EV BOARD ORDERING INFORMATION

| EV Board Part No. | EV Board Version No.    | Remarks |
|-------------------|-------------------------|---------|
| MB39C006AEVB-06   | MB39C006AEVB-06 Rev.2.0 | SON10   |

## ■ PACKAGE DIMENSION

|                                                                                                                                  |                       |
|----------------------------------------------------------------------------------------------------------------------------------|-----------------------|
| 10-pin plastic SON<br><br><br><br>(LCC-10P-M04) | Lead pitch<br>0.50 mm |
| Package width × package length<br>3.00 mm × 3.00 mm                                                                              |                       |
| Sealing method<br>Plastic mold                                                                                                   |                       |
| Mounting height<br>0.75 mm MAX                                                                                                   |                       |
| Weight<br>0.018 g                                                                                                                |                       |
|                                                                                                                                  |                       |
|                                                                                                                                  |                       |



Please confirm the latest Package dimension by following URL.  
<http://edevice.fujitsu.com/package/en-search/>

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